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## Chip Monolithic Ceramic Capacitor meet AEC-Q200 for Infotainment GRT1555C1H330JA02\_ (0402, C0G:EIA, 33pF, DC50V)

\_: packaging code

**Reference Sheet** 

## 1.Scope

This product specification is applied to Chip Monolithic Ceramic Capacitor used for Car Multimedia, Car Interior, Car Comfort application and General Electronic equipment.

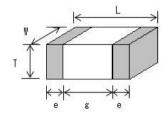
Please contact us when using this product for any other applications than described in the above.

Do not use these products in applications critical to passenger safety and car driving function (e.g. ABS, AIRBAG, etc.).

## 2.MURATA Part NO. System

GRT 15 5C 1H 330 A02 J (4)Rated Voltage (1)L/W Dimensions (2)T Dimensions (3)Temperature Characteristics (5)Nominal Capacitance (6)Capacitance Tolerance (7)Murata's Control (8)Packaging Code

## 3. Type & Dimensions



(Unit:mm)

1

				(•)
(1)-1 L	(1)-2 W	(2) T	е	g
1.0±0.05	0.5±0.05	0.5±0.05	0.15 to 0.35	0.3 min.

## 4.Rated value

(3) Temperature (Public STD C	(4) Rated	(5) Nominal	(6) Capacitance	Specifications and Test Methods		
Temp. coeff or Cap. Change	Temp. Range (Ref.Temp.)	Voltage	Capacitance	Tolerance	(Operating Temp. Range)	
0±30 ppm/°C	25 to 125 °C (25 °C)	DC 50 V	33 pF	±5 %	-55 to 125 °C	

5.Package

mark	(8) Packaging	Packaging Unit
D	φ180mm Reel PAPER W8P2	10000 pcs./Reel
W	φ180mm Reel PAPER W8P1	20000 pcs./Reel
J	φ330mm Reel PAPER W8P2	50000 pcs./Reel

Product specifications in this catalog are as of Apr.8,2016,and are subject to change or obsolescence without notice. Please consult the approval sheet before ordering.

Please read rating and !Cautions first.

# ■AEC-Q200 Murata Standard Specification and Test Methods

			Specification	ns.					
No	AEC-Q20	00 Test Item	Temperature Compensating Type	High Dielectric Type	AEC-Q200 Test Method				
1	Pre-and Post-	Stress		_					
'	Electrical Tes	t							
2	High Tempera	ature	The measured and observed characteristics sho	ould satisfy the	Set the capacitor for 1000±12 hours at 125±3°C.				
	Exposure (Sto	rage)	specifications in the following table.		Set for 24±2 hours at room temperature, then measure.				
		Appearance	No marking defects						
		Capacitance	Within ±2.5% or ±0.25pF	R7: Within ±12.5%					
		Change	(Whichever is larger)						
		Q/D.F.	30pFmin. : Q≧350	R7: 0.2 max.					
			10pF and over, 30pF and below:Q≧275+5C/2						
			10pFmax.: Q ≧200+10C						
			C: Nominal Capacitance(pF)						
		Insulation	More than 10,000MΩ or 500Ω·F	R7: More than 500MΩ or 25Ω·F					
		Resistance	(Whichever is smaller)	(Whichever is smaller)					
3	Temperature	Cycling	The measured and observed characteristics sho	ould satisfy the	Fix the capacitor to the supporting jig in the same manner and under				
			specifications in the following table.		the same conditions as (18). Perform cycles test according				
		Appearance	No marking defects		to the four heat treatments in the following table.				
		Capacitance	Within ±2.5% or ±0.25pF		Set for 24±2 hours at room temperature, then measure.				
		Change	(Whichever is larger)		Step Time (min) Cycles				
		Q/D.F.	30pFmin. : Q≧1000	R7: 0.2 max.	1000 (for ΔC/R7) 5 (for ΔC/R7)				
			30pFmax.: Q ≧400+20C		1 15±3 -40°C+0/-3 -55°C+0/-3				
			C: Nominal Capacitance(pF)		2 1 Room Room				
					3 15±3 105°C+3/-0 125°C+3/-0				
		Insulation	More than 10,000MΩ or 500Ω•F	R7: More than 1,000MΩ or 50Ω•F	4 1 Room Room				
		Resistance	(Whichever is smaller)	(Whichever is smaller)	·Initial measurement for high dielectric constant type				
					Perform a heat treatment at 150+0/-10 °C for one hour and then set for 24±2 hours at room temperature.  Perform the initial measurement.				
4	Destructive		No defects or abnormalities		Per EIA-469				
	Phisical Analy	/sis							
5	Biased Humid	lity	The measured and observed characteristics sho	ould satisfy the	Apply the rated voltage and 1.3+0.2/-0vdc (add 6.8kΩ resister)				
			specifications in the following table.		at 85±3°C and 80 to 85% humidity for 1000±12 hours.				
		Appearance	No marking defects		Remove and set for 24±2 hours at room temprature, then measure.				
		Capacitance	Within ±3.0% or ±0.30pF	R7: Within ±12.5%	The charge/discharge current is less than 50mA.				
		Change	(Whichever is larger)						
		Q/D.F.	30pF and over: Q≧200	R7: 0.2 max	Measurement after test for high dielectric constant type				
			30pF and below: Q≧100+10C/3		Perform a heat treatment at 150+0/–10°C for one hour and then let				
			C: Nominal Capacitance(pF)		sit for 24±2 hours at room temperature, then measure.				
		Insulation	More than 1,000MΩ or 50Ω•F	R7: More than 100MΩ or 5Ω•F	7				
		Resistance	(Whichever is smaller)	(Whichever is smaller)					

Appearance   Appearance   No marking defects   R7: Within the specified dimensions   Visual inspection   Virbin the specified dimensions   Virbin the specified di	AEC-Q200 Test Method  AEC-Q200 Test Method  AEC-Q200 Test Method  Apply 100% of the rated voltage for 1000±12 hours at 125±3°C. Set for 24±2 hours at room temperature, then measure.  The charge/discharge current is less than 50mA.  R7: Within ±12.5%  Initial measurement for high dielectric constant type  Perform a heat treatment at 150+00-10°C for one hour and then set for 24±2 hours at room temperature.  Perform the initial measurement.  -Neasurement afterset  Perform a heat treatment at 150+00-10°C for one hour and then set for 24±2 hours at room temperature, then measure.  -Neasurement afterset  Perform a heat treatment at 150+00-10°C for one hour and then set at for 24±2 hours at room temperature, then measure.  -Neasurement afterset  Perform a heat treatment at 150+00-10°C for one hour and then set at for 24±2 hours at room temperature, then measure.  -Neasurement afterset  Perform a heat treatment at 150+00-10°C for one hour and then set at for 24±2 hours at room temperature, then measure.  -Neasurement afterset  Perform a heat treatment at 150+00-10°C for one hour and then set for 24±2 hours at room temperature, then measure.  -Neasurement afterset  Perform a heat treatment at 150+00-10°C for one hour and then set for 24±2 hours at room temperature, then measure.  -Neasurement afterset  -Neasurement afte	۷o			0		T
Compensating Type	Agoly 100% of the rated voltage for 100±12 hours at 125±3°C.  Sot for 24±2 hours at room temperature, then measure.  The charge/discharge current is less than 50mA.  R7: Within ±12.5%  1-hitial measurement for high dielectric constant type Perform a heat treatment at 150+0/-10°C for one hour and then set for 24±2 hours at room temperature. Perform the initial measurement.	•	AFC-O2	00 Test Item	· · · · · · · · · · · · · · · · · · ·	cations.	AFC-O200 Test Method
Department Life	Apply 100% of the rated voltage for 1000±12 hours at 125±3°C.  Sot for 24±2 hours at room temperature, then measure.  The charge/discharge current is less than 50mA.  170 2max  Perform a heat treatment at 150+0′-10°C for one hour and then set for 24±2 hours at room temperature. Perform the initial measurement.		ALO-QZ	oo rest item		High Dielectric Type	ALC-Q200 Test Method
Set for 24-2 hours at room temperature, then measure. The changel displace unreal is less than 50m A. Proposation of Within 13.0% or 20.30 pF (Whichever is larger) (Whichever	Set for 24±2 hours at room temperature, then measure.  R7: Within ±12.5%  Intercharge/discharge current is less than 50mA.  Intercharge/discharge current is less than 150mA.  Intercharge	6	Operational Life	9		teristics should satisfy the	Apply 100% of the rated voltage for 1000+12 hours at 125 ± 3°C
Appearance   No marking defects   N7. Within ±12.5%   The chargedischarge current is less than 50mA, Capacitance   Within ±3.0% or ±3.09F   N7. Within ±12.5%   Initial measurement for high dielectric constant type   Perform the initial measurement or high dielectric constant type   Perform the initial measurement at 150+01-10°C for one hour and for 24.22 hours at room temperature.   Perform the initial measurement.   Perform the i	R7: Within ±12.5%   Initial measurement for high dielectric constant type	٠,	Operational Lin			teriolico criodia dallory life	
Capacitance   Within s.300 for d.303pF   R7. Within s.12.5%   Principle   Principle   R7. 0.2max   Principle   Principle   R7. 0.2max   Principle	Perform a heat treatment at 150+0/-10°C for one hour and then set for 24±2 hours at room temperature. Perform the initial measurement.			Annograpeo			•
Change   Office   Office   Supprime   Capacidance   Office   Capacidance   Capacidan	-Initial measurement for high dielectric constant type Perform a heat treatment at 150+00-10°C for one hour and then set for 242-2 hours at room temperature. Perform the initial measurement.					D7. Within 142 F0/	The charge/discharge current is less than 30mA.
QD.F.   30pFmin.: Calcabota   R7: 0.2max   Perform a heat treatment at 150-W-10°C for one hour and for 24±2 hours at room temperature.   Perform the initial measurement.   Perform the init	Perform a heat treatment at 150+0/-10°C for one hour and then set for 24±2 hours at room temperature. Perform the initial measurement.  -Measurement at 150+0/-10°C for one hour and then set for 24±2 hours at room temperature. Perform a heat treatment at 150+0/-10°C for one hour and then let sit for 24±2 hours at room temperature, then measure.    Visual inspection				· ·	K7. WIUIIII ±12.5%	Initial management for high dialocatic constant type
10pF and over, 30pF and below: 0275-9502   10pFmax: 0 2 200-100	for 24±2 hours at room temperature.						
C≥275-5C/2   Perform the initial measurement.   Perform the initial measurement.   Perform the initial measurement.	Perform the initial measurement.			Q/D.F.	· ·	R7: 0.2max	
10pFmax: Q ≥ 200+10C   C: Nominal Capacitance(pF)   Perform a heat treatment at 150+00-10°C for one hour and noting of 50Ω + Final (Whichever is smaller)   R?: More than 100MΩ or 5Ω · Final (Whichever is smaller)   Perform a heat treatment at 150+00-10°C for one hour and sit for 24±2 hours at room temperature, then measure.    Perform a heat treatment at 150+00-10°C for one hour and sit for 24±2 hours at room temperature, then measure.    Perform a heat treatment at 150+00-10°C for one hour and sit for 24±2 hours at room temperature, then measure.    Perform a heat treatment at 150+00-10°C for one hour and sit for 24±2 hours at room temperature, then measure.    Perform a heat treatment at 150+00-10°C for one hour and sit for 24±2 hours at room temperature, then measure.    Perform a heat treatment at 150+00-10°C for one hour and sit for 24±2 hours at room temperature, then measure.    Perform a heat treatment at 150+00-10°C for one hour and sit for 24±2 hours at room temperature, then measure.    Perform a heat treatment at 150+00-10°C for one hour and sit for 24±2 hours at room temperature, then measure.    Perform a heat treatment at 150+00-10°C for one hour and sit for 24±2 hours at room temperature, then measure.    Perform a heat treatment at 150+00-10°C for one hour and sit for 24±2 hours at room temperature, then measure.    Perform a heat treatment at 150+00-10°C for one hour and sit for 24±2 hours at room temperature, then measure.    Perform a heat treatment at 150+00-10°C for one hour and sit for 24±2 hours at room temperature.   Perform a heat treatment at 150+00-10°C for one hour and sit for 24±2 hours at room temperature.   Perform a heat treatment at 150+00-10°C for one hour and sit for 24±2 hours at room temperature of 150+00-10°C for one hour and sit for 24±2 hours at room temperature.   Perform a heat treatment at 150+00-10°C for one hour and sit for 24±2 hours at room temperature of 150+00-10°C for one hour and sit for 24±2 hours at room temperature of 150+00-10°C for one hour and sit fo	-Measurement after test  A7: More than 100MΩ or 5Ω ·F (Whichever is smaller)  Wisual inspection  Using calipers  Per MIL-STD-202 Method 215  Solvent 1 : 1 part (by volume) of isopropyl alcohol 3 parts (by volume) of isopropyl alcohol 3 parts (by volume) of mineral spirits  Solvent 2 : Terpene defluxer  Solvent 3 : 42 parts (by volume) of monoethanolorrine  A7: 0.125max  Solvent 3 : 42 parts (by volume) of monoethanolorrine  Three shocks in each direction should be applied along 3 mutually perpendicular axes of the test specimen (18 shocks).  The specified test pulse should be Half-sine and should have a duration : 0.5ms, peak value:1500g and velocity change: 4.7m/s.  Solvent 3 : 45 parts (by volume) of monoethanolorrine  A7: 0.125max  A7: 0.125max  Solvent 3 : 45 parts (by volume) of monoethanolorrine  Three shocks in each direction should be applied along 3 mutually perpendicular axes of the test specimen (18 shocks).  The specified test pulse should be Half-sine and should have a duration : 0.5ms, peak value:1500g and velocity change: 4.7m/s.  Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 terms in each 3 mutually perpendicular directions (total of 36 times).  R7: 0.125max  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Initial measurement for high dielectric constant type Perform a heat treatment at 150+0/-10 °C for one hour and then set						·
C: Nominal Capacitance(pF)   Insulation   More than 1,000MQ or 50 0 F   R?: More than 100MQ or 50 F   R?: More than 100MQ o	R7: More than 100MΩ or 5Ω · F (Whichever is smaller)    Visual inspection						Perform the initial measurement.
Insulation   More than 1,000MΩ or 500 F   R7: More than 100MΩ or 50 F   Reintance   (Whichever is smaller)   Within the specified dimensions   Using calipres	R7: More than 100MΩ or 5Ω · F (Whichever is smaller)    Visual inspection				10pFmax.: Q ≧200+10C		
Resistance   Whichever is smaller)   Whichever is smaller)   Stit for 24±2 hours at room temperature, then measure.    Resistance to   Priscal Dimension   Within the specified dimensions   Using calipers	Site for 24±2 hours at room temperature, then measure.				C: Nominal Capacitance(pF)		Measurement after test
Prisical Dimension	Visual inspection			Insulation	More than 1,000M $\Omega$ or 50 $\Omega$ •F	R7: More than $100M\Omega$ or $5\Omega \cdot F$	Perform a heat treatment at 150+0/–10°C for one hour and then let
8 Phisical Dimersion Within the specified dimensions Using calipers  9 Resistance to Solvents Part (by volume) of mineral spirits Solvents (Capacitance Capacitance) (Within the specified tolerance Change	Using calipers			Resistance	(Whichever is smaller)	(Whichever is smaller)	sit for 24±2 hours at room temperature, then measure.
Phiscial Dimersion   Within the specified dimensions   Using calipers	Using calipers						
Resistance to Solvents   Appearance   No marking defects   Solvent   Capacitance   Change	Per MIL-STD-202 Method 215 Solvent 1 : 1 part (by volume) of isopropyl alcohol 3 parts (by volume) of mineral spirits Solvent 2 : Terpene defluxer Solvent 3 : 42 parts (by volume) of propylene glycol monomethylether 1 part (by volume) of propylene glycol monomethylether 1 part (by volume) of propylene glycol monomethylether 1 part (by volume) of monoethanolomine  Three shocks in each direction should be applied along 3 mutually perpendicular axes of the test specimen (18 shocks). The specified test pulse should be Half-sine and should have a duration :0.5ms, peak value:1500g and velocity change: 4.7m/s.  e(pF)  Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  Three shocks in each direction should be tayled along 3 mutually perpendicular directions (total of 36 times).	7	External Visual	•	No defects or abnormalities	-	Visual inspection
9 Resistance to Change   Appearance   No marking defects   Solvent   Solve	Per MIL-STD-202 Method 215 Solvent 1 : 1 part (by volume) of isopropyl alcohol 3 parts (by volume) of mineral spirits Solvent 2 : Terpene defluxer Solvent 3 : 42 parts (by volume) of propylene glycol monomethylether 1 part (by volume) of propylene glycol monomethylether 1 part (by volume) of propylene glycol monomethylether 1 part (by volume) of monoethanolomine  Three shocks in each direction should be applied along 3 mutually perpendicular axes of the test specimen (18 shocks). The specified test pulse should be Half-sine and should have a duration :0.5ms, peak value:1500g and velocity change: 4.7m/s.  e(pF)  Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  Three shocks in each direction should be tayled along 3 mutually perpendicular directions (total of 36 times).						
Solvents    Capacitance   Change   Ch	Solvent 1 : 1 part (by volume) of isopropyl alcohol 3 parts (by volume) of mineral spirits Solvent 2 : Terpene defluxer Solvent 3 : 42 parts (by volume) of water 1 part (by volume) of propylene glycol monomethylether 1 part (by volume) of propylene glycol monomethylether 1 part (by volume) of monoethanolomine  Three shocks in each direction should be applied along 3 mutually perpendicular axes of the test specimen (18 shocks). The specified test pulse should be Half-sine and should have a duration :0.5ms, peak value:1500g and velocity change: 4.7m/s.  R7: 0.125max  Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximately 20 minutes. This motion should be applied for 12 terms in each 3 mutually perpendicular directions (total of 36 times).  R7: 0.125max  F7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)	8	Phisical Dimen	sion	Within the specified dimensions		Using calipers
Solvents    Capacitance Change   Within the specified tolerance   Change   Change	Solvent 1 : 1 part (by volume) of isopropyl alcohol 3 parts (by volume) of mineral spirits Solvent 2 : Terpene defluxer Solvent 3 : 42 parts (by volume) of water 1 part (by volume) of propylene glycol monomethylether 1 part (by volume) of propylene glycol monomethylether 1 part (by volume) of monoethanolomine  Three shocks in each direction should be applied along 3 mutually perpendicular axes of the test specimen (18 shocks). The specified test pulse should be Half-sine and should have a duration :0.5ms, peak value:1500g and velocity change: 4.7m/s.  R7: 0.125max  Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximatel limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  R7: 0.125max  F7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Immerse the capacitor on a heat treatment at 150+0/-10 °C for one hour and then set						
Change  Q/D.F.  30pFmin: Q≥1000  30pFmin: Q≥400420C  C: Nominal Capacitance(pF)  Insulation  More than 10,000MΩ or 500Q · F  (Whichever is smaller)  Mechanical  Shock  Appearance  O/D.F.  30pFmin: Q≥1000  Mechanical  Shock  Capacitance  Change  Q/D.F.  30pFmin: Q≥1000  30pFmin: Q≥1000  R7: More than 1000MΩ or 50Q · F  (Whichever is smaller)  Three shocks in each direction should be applied along 3 r  perpendicular axes of the test specimen (18 shocks). The specified test pulse should be Half-sine and should ha  duration :0.5ms, peak value:1500g and velocity change: 4.  30pFmin: Q≥1000  R7: 0.125max  John or than 10,000MΩ or 500Q · F  (Whichever is smaller)  No defects or abnormalities  Capacitance  Change  Q/D.F.  30pFmin: Q≥1000  Appearance  No defects or abnormalities  Capacitance  Within the specified tolerance  Change  Q/D.F.  30pFmin: Q≥1000  R7: 0.125max  Solder the capacitor to the test jig (glass epoxy board) in the manner and under the same conditions as (18). The capacitance of the capacitor of 1.5mm, the frequency being varied uniformly the approximately 20 minutes. This motion should be applied in approximately 20 minutes. This motion should be applied in the specified tolerance of the capacitor for the test jig (plass epoxy board) in the approximately into 10Hz, should be traversed in approximately 20 minutes. This motion should be applied in the specified tolerance of the proximately 20 minutes. This motion should be applied in the specified tolerance of the proximately 20 minutes. This motion should be applied in the specified tolerance of the proximately 20 minutes. This motion should be applied in the specified tolerance of the proximately 20 minutes. This motion should be applied in the specified tolerance of the proximately 20 minutes. This motion should be applied in the specified tolerance of the proximately 20 minutes. This motion should be applied in the specified tolerance of the proximately 20 minutes. This motion should be applied in the specified approximately 20 minutes. This motio	3 parts (by volume) of mineral spirits  Solvent 2 : Terpene defluxer  Solvent 3 : 42 parts (by volume) of propylene glycol monomethylether  1 part (by volume) of propylene glycol monomethylether  1 part (by volume) of monoethanolomine  Three shocks in each direction should be applied along 3 mutually perpendicular axes of the test specimen (18 shocks).  The specified test pulse should be Half-sine and should have a duration :0.5ms, peak value:1500g and velocity change: 4.7m/s.  Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  R7: 0.125max  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Initial measurement for high dielectric constant type  Perform a heat treatment at 150+0/-10 °C for one hour and then set	9	Resistance to	Appearance	No marking defects		Per MIL-STD-202 Method 215
Change  Q/D.F.  30pFmin: Q≥1000  30pFmin: Q≥400420C  C: Nominal Capacitance(pF)  Insulation  More than 10,000MΩ or 500Q · F  (Whichever is smaller)  Mechanical  Shock  Appearance  O/D.F.  30pFmin: Q≥1000  Mechanical  Shock  Capacitance  Change  Q/D.F.  30pFmin: Q≥1000  30pFmin: Q≥1000  R7: More than 1000MΩ or 50Q · F  (Whichever is smaller)  Three shocks in each direction should be applied along 3 r  perpendicular axes of the test specimen (18 shocks). The specified test pulse should be Half-sine and should ha  duration :0.5ms, peak value:1500g and velocity change: 4.  30pFmin: Q≥1000  R7: 0.125max  John or than 10,000MΩ or 500Q · F  (Whichever is smaller)  No defects or abnormalities  Capacitance  Change  Q/D.F.  30pFmin: Q≥1000  Appearance  No defects or abnormalities  Capacitance  Within the specified tolerance  Change  Q/D.F.  30pFmin: Q≥1000  R7: 0.125max  Solder the capacitor to the test jig (glass epoxy board) in the manner and under the same conditions as (18). The capacitance of the capacitor of 1.5mm, the frequency being varied uniformly the approximately 20 minutes. This motion should be applied in approximately 20 minutes. This motion should be applied in the specified tolerance of the capacitor for the test jig (plass epoxy board) in the approximately into 10Hz, should be traversed in approximately 20 minutes. This motion should be applied in the specified tolerance of the proximately 20 minutes. This motion should be applied in the specified tolerance of the proximately 20 minutes. This motion should be applied in the specified tolerance of the proximately 20 minutes. This motion should be applied in the specified tolerance of the proximately 20 minutes. This motion should be applied in the specified tolerance of the proximately 20 minutes. This motion should be applied in the specified tolerance of the proximately 20 minutes. This motion should be applied in the specified tolerance of the proximately 20 minutes. This motion should be applied in the specified approximately 20 minutes. This motio	3 parts (by volume) of mineral spirits  Solvent 2 : Terpene defluxer  Solvent 3 : 42 parts (by volume) of propylene glycol monomethylether  1 part (by volume) of propylene glycol monomethylether  1 part (by volume) of monoethanolomine  Three shocks in each direction should be applied along 3 mutually perpendicular axes of the test specimen (18 shocks).  The specified test pulse should be Half-sine and should have a duration :0.5ms, peak value:1500g and velocity change: 4.7m/s.  Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  R7: 0.125max  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Initial measurement for high dielectric constant type  Perform a heat treatment at 150+0/-10 °C for one hour and then set		Solvents		Within the specified tolerance		Solvent 1 : 1 part (by volume) of isopropyl alcohol
Q/D.F.   S0pFmin.: Q≥1000   R7: 0.125max   Solvent 2: Terpene defluxer   Solvent 3: 42 parts (by volume) of water   1 part (by volume) of propylene glycol monomic   1 part (by volume) of monoethanolomine   1 part (by volume) of worthanolomine   1 part (by volume) of worthan   1 part (by volume) of worthanolomine   1 part (by volume) of worthan   1 part (by volume) of worthanolomine   1 part (by volume) of worthan   1 part (by volume) of worthanolomine   1 part (by volume) of worthan   1 part (by volume) of monoethanolomine   1 part (by volume) of worthan   1 part (by volume) of monoethanolomine   1 part (by volume) of worthan   1 pa	R7: 0.125max   Solvent 2 : Terpene defluxer   Solvent 3 : 42 parts (by volume) of water   1 part (by volume) of propylene glycol monomethylether   1 part (by volume) of monoethanolomine   1 part (by volume) of monoethanolomica   1 part (by						
Solvent 3 : 42 parts (by volume) of water  1 part (by volume) of propylene glycol monome 1 part (by volume) of monoethanolomine  1 part (by volume) of monoethanolomine 1 part (by volume) of monoethanolomine 1 part (by volume) of monoethanolomine 1 part (by volume) of monoethanolomine 1 part (by volume) of monoethanolomine 1 part (by volume) of monoethanolomine 1 part (by volume) of monoethanolomine 1 part (by volume) of monoethanolomine 1 part (by volume) of monoethanolomine 1 part (by volume) of monoethanolomine 1 part (by volume) of propylene glycol monome 1 part (by volume) of monoethanolomine 1 part (by volume) of monoethanolomine 1 part (by volume) of propylene glycol monome 1 part (by volume) of monoethanolomine 1 part (by volume) of monoethanolomic motors 1 part (by volume) of propylene in the same and direction should be applied for perpendicular axes of the test specified to the	Solvent 3 : 42 parts (by volume) of water  1 part (by volume) of propylene glycol monomethylether  1 part (by volume) of monoethanolomine  Three shocks in each direction should be applied along 3 mutually perpendicular axes of the test specimen (18 shocks).  The specified test pulse should be Half-sine and should have a duration :0.5ms, peak value:1500g and velocity change: 4.7m/s.  R7: 0.125max  Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12  000 ·F  R7: More than 1000MΩ or 50Ω ·F  (Whichever is smaller)  Three shocks in each direction should be applied along 3 mutually perpendicular directions (total of 36 times).  Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximatel limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 terms in each 3 mutually perpendicular directions (total of 36 times).  Immerse the capacitor in a eutectic solder solution at 260 ±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Ince  Initial measurement for high dielectric constant type  Perform a heat treatment at 150+0/-10 °C for one hour and then set				30pFmin. : Q≧1000	R7: 0.125max	
C: Nominal Capacitance (PF)  Insulation Resistance  (Whichever is smaller)  Mechanical Shock  Appearance Change  (Vi) Insulation Resistance  (Whichever is smaller)  No marking defects Capacitance Change  (Vi) Insulation Resistance  (Vi) Insulation Resistance  (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Resistance (Vi) Insulation Insulation Resistance (Vi) Insulation Re	1 part (by volume) of propylene glycol monomethylether 1 part (by volume) of monoethanolomine  Three shocks in each direction should be applied along 3 mutually perpendicular axes of the test specimen (18 shocks). The specified test pulse should be Half-sine and should have a duration :0.5ms, peak value:1500g and velocity change: 4.7m/s.  R7: 0.125max  Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximatel limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  R7: 0.125max  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Initial measurement for high dielectric constant type  Perform a heat treatment at 150+0/-10 °C for one hour and then set				· ·		·
1 part (by volume) of monoethanolomine	1 part (by volume) of monoethanolomine  1 part (by volume) of monoethanolomica  1 part (by volume) of the state powers  1 par				· ·		
Insulation Resistance   More than 10,000MΩ or 500Ω · F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)	Three shocks in each direction should be applied along 3 mutually perpendicular axes of the test specimen (18 shocks).  The specified test pulse should be Half-sine and should have a duration :0.5ms, peak value:1500g and velocity change: 4.7m/s.  R7: 0.125max  Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be taversed in approximately 20 minutes. This motion should be applied for 12 (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Initial measurement for high dielectric constant type  Perform a heat treatment at 150+0/-10 °C for one hour and then set				C. Nominal Capacitance(pr)		
Resistance   (Whichever is smaller)   (Whichever is smaller)	Three shocks in each direction should be applied along 3 mutually perpendicular axes of the test specimen (18 shocks).  The specified test pulse should be Half-sine and should have a duration :0.5ms, peak value:1500g and velocity change: 4.7m/s.    R7: 0.125max			Inculation	Mara than 10 000MO at 5000 . F	D7: Mare than 1000MO at 500 F	
Mechanical Shock   Appearance   No marking defects   Three shocks in each direction should be applied along 3 of perpendicular axes of the test specimen (18 shocks). The specified test pulse should be Half-sine and should had duration: 0.5ms, peak value:1500g and velocity change: 4.	Three shocks in each direction should be applied along 3 mutually perpendicular axes of the test specimen (18 shocks).  The specified test pulse should be Half-sine and should have a duration :0.5ms, peak value:1500g and velocity change: 4.7m/s.  Part More than 1000MΩ or 50Ω · F  (Whichever is smaller)  Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12  DΩΩ · F  R7: More than 1000MΩ or 50Ω · F  (Whichever is smaller)  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Ince  R7: 0.125max  Perform a heat treatment at 150+0/-10 °C for one hour and then set				,		
Shock Capacitance Change  Q/D.F.  30pFmin.: Q≥1000 30pFmax.: Q≥400+20C C: Nominal Capacitance(pF)  Insulation Resistance Change  Appearance Change  Appearance Change  Q/D.F.  30pFmin.: Q≥1000 30pFmax.: Q≥400+20C C: Nominal Capacitance(pF)  Insulation Resistance Change  Appearance Change  Appearance Change  Q/D.F.  30pFmin.: Q≥1000 R7: More than 1000MΩ or 50Ω • F (Whichever is smaller)  Appearance Change  Q/D.F.  30pFmin.: Q≥1000 30pFmax.: Q≥400+20C C: Nominal Capacitance Change  Appearance Change  Q/D.F.  30pFmin.: Q≥1000 30pFmax.: Q≥400+20C C: Nominal Capacitance(pF)  Insulation Resistance  Nor ethan 10,000MΩ or 50Ω • F (Whichever is smaller)  R7: 0.125max  amplitude of 1.5mm, the frequency being varied uniformly the approximate limits of 10 and 2000Hz. The frequency rare 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 15mm in each 3 mutually perpendicular directions (total of 3 mature)  Resistance  The measured and observed characteristics should satisfy the specifications in the following table.  Immerse the capacitor in a eutectic solder solution at 260±10±10±10±10±10±10±10±10±10±10±10±10±10	perpendicular axes of the test specimen (18 shocks). The specified test pulse should be Half-sine and should have a duration :0.5ms, peak value:1500g and velocity change: 4.7m/s.  Pe(pF)  R7: More than 1000MΩ or 50Ω • F (Whichever is smaller)  Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  R7: More than 1000MΩ or 50Ω • F (Whichever is smaller)  Perform a heat treatment at 150+0/-10 °C for one hour and then set			Resistance	(Whichever is smaller)	(Whichever is smaller)	
Shock Capacitance Change  Q/D.F.  30pFmin.: Q≥1000 30pFmax.: Q≥400+20C C: Nominal Capacitance(pF)  Insulation Resistance Change  Appearance Change  Appearance Change  Q/D.F.  30pFmin.: Q≥1000 30pFmax.: Q≥400+20C C: Nominal Capacitance(pF)  Insulation Resistance Change  Appearance Change  Appearance Change  Q/D.F.  30pFmin.: Q≥1000 R7: More than 1000MΩ or 50Ω • F (Whichever is smaller)  Appearance Change  Q/D.F.  30pFmin.: Q≥1000 30pFmax.: Q≥400+20C C: Nominal Capacitance Change  Appearance Change  Q/D.F.  30pFmin.: Q≥1000 30pFmax.: Q≥400+20C C: Nominal Capacitance(pF)  Insulation Resistance  Nor ethan 10,000MΩ or 50Ω • F (Whichever is smaller)  R7: 0.125max  amplitude of 1.5mm, the frequency being varied uniformly the approximate limits of 10 and 2000Hz. The frequency rare 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 15mm in each 3 mutually perpendicular directions (total of 3 mature)  Resistance  The measured and observed characteristics should satisfy the specifications in the following table.  Immerse the capacitor in a eutectic solder solution at 260±10±10±10±10±10±10±10±10±10±10±10±10±10	perpendicular axes of the test specimen (18 shocks). The specified test pulse should be Half-sine and should have a duration :0.5ms, peak value:1500g and velocity change: 4.7m/s.  Pe(pF)  R7: More than 1000MΩ or 50Ω • F (Whichever is smaller)  Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  R7: More than 1000MΩ or 50Ω • F (Whichever is smaller)  Perform a heat treatment at 150+0/-10 °C for one hour and then set						
Shock Capacitance Change  Q/D.F.  30pFmin.: Q≥1000 30pFmax.: Q≥400+20C C: Nominal Capacitance(pF)  Insulation Resistance Change  Appearance Change  Appearance Change  Q/D.F.  30pFmin.: Q≥1000 30pFmax.: Q≥400+20C C: Nominal Capacitance(pF)  Insulation Resistance Change  Appearance Change  Appearance Change  Q/D.F.  30pFmin.: Q≥1000 R7: More than 1000MΩ or 500 · F (Whichever is smaller)  Appearance Change  Q/D.F.  30pFmin.: Q≥1000 30pFmax.: Q≥400+20C C: Nominal Capacitance Change  Q/D.F.  30pFmin.: Q≥1000 30pFmax.: Q≥400+20C C: Nominal Capacitance(pF)  Insulation Resistance  R7: 0.125max  Appearance Appearance Change  Appearance Change  Q/D.F.  30pFmin.: Q≥1000 30pFmax.: Q≥400+20C C: Nominal Capacitance(pF)  Insulation Resistance  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  Insulation Resistance  The measured and observed characteristics should satisfy the specifications in the following table.  Immerse the capacitor in a eutectic solder solution at 260±10±1 seconds. Set at room temperature for 24±2 hours, the specifications in the following table.	perpendicular axes of the test specimen (18 shocks). The specified test pulse should be Half-sine and should have a duration :0.5ms, peak value:1500g and velocity change: 4.7m/s.  Pe(pF)  R7: More than 1000MΩ or 50Ω • F (Whichever is smaller)  Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  R7: More than 1000MΩ or 50Ω • F (Whichever is smaller)  Perform a heat treatment at 150+0/-10 °C for one hour and then set			_			
The specified test pulse should be Half-sine and should hald duration :0.5ms, peak value:1500g and velocity change: 4.    Solder the capacitor to the test jig (glass epoxy board) in the specified tolerance within the specified tolerance change   Q/D.F.   30pFmin.: Q≥ 1000   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   Solder the capacitor to the test jig (glass epoxy board) in the manner and under the same conditions as (18). The capacitor change   Q/D.F.   30pFmin.: Q≥ 1000   R7: 0.125max   30pFmin.: Q≥ 400+20C   C: Nominal Capacitance(pF)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)   R	The specified test pulse should be Half-sine and should have a duration :0.5ms, peak value:1500g and velocity change: 4.7m/s.  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Ince  R7: 0.125max  Prior in a heat treatment at 150+0/-10 °C for one hour and then set	10					
Q/D.F.   30pFmin.: Q≥1000   R7: 0.125max   duration :0.5ms, peak value:1500g and velocity change: 4.	R7: 0.125max   duration :0.5ms, peak value:1500g and velocity change: 4.7m/s.		Shock	Capacitance	Within the specified tolerance		
Solder the capacitor to the test jig (glass epoxy board) in the specifications in the following table.	Perform a heat treatment at 150+0/-10 °C for one hour and then set			Change			The specified test pulse should be Half-sine and should have a
Insulation   More than 10,000MΩ or 500Ω · F   R7: More than 1000MΩ or 50Ω · F   (Whichever is smaller)	Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000			Q/D.F.	30pFmin. : Q≧1000	R7: 0.125max	duration :0.5ms, peak value:1500g and velocity change: 4.7m/s.
Insulation Resistance (Whichever is smaller)  No defects or abnormalities  Capacitance Change  Q/D.F. 30pFmin.: Q≥1000 30pFmax.: Q≥400+20C C: Nominal Capacitance(pF)  Insulation Resistance  R7: More than 1000MΩ or 50Ω • F (Whichever is smaller)  R7: 0.125max amplitude of 1.5mm, the frequency being varied uniformly the approximatel limits of 10 and 2000Hz. The frequency ratio 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for the smaller)  R7: More than 1000MΩ or 50Ω • F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω • F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω • F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω • F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω • F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω • F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω • F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω • F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω • F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω • F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω • F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω • F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω • F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω • F (Whichever is smaller)	Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000MΩ or 50Ω · F (Whichever is smaller)  BY: More than 1000				30pFmax.: Q ≧400+20C		
Resistance (Whichever is smaller) (Whichever is smaller)  Appearance No defects or abnormalities Capacitance Change Within the specified tolerance Change Appearance No defects or abnormalities  Q/D.F. 30pFmin.: Q≥1000 R7: 0.125max amplitude of 1.5mm, the frequency being varied uniformly the approximate limits of 10 and 2000Hz. The frequency rate of 10 to 2000Hz and return to 10Hz, should be applied for items in each 3 mutually perpendicular directions (total of 3 mutually perpendicular directions (total of 3 mutually perpendicular directions total of 3 specifications in the following table.  Resistance to Soldering Heat Soldering Heat  Resistance (Whichever is smaller) (Whichever is smaller)  Whichever is smaller) (Whichever is a maller) (Whichever is a eutectic solder solution at 260± 10±1 seconds. Set at room temperature for 24±2 hours, the smaller of the test jig (glass epoxy board) in the manner and under the same conditions as (18). The capacitor to the test jig (glass epoxy board) in the manner and under the same conditions as (18). The capacitor having a manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a manner and under the same conditions as (18). The capacitor having a manner and under the same conditions as (18). The capacitor having a manner and under the same conditions as (18). The capacitor having a manner and under the same conditions as (18). The capacitor having a manner and under the same conditions as (18). The capacitor having a manner and under the same conditions as (18). The capacitor having a manner and under the same conditions as (18). The capacitor having a manner and under the same conditions as (18). The capacitor having a manner and under the same conditions as (18). The capacitor having a manner and under the same conditions as (18). The capacitor having a manner and under the same conditions as (18). The capacitor having a manner and under the same conditions as (18). The capacitor having a manner and under the	Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).    Condition   Co				C: Nominal Capacitance(pF)		
Resistance (Whichever is smaller) (Whichever is smaller)  Appearance No defects or abnormalities Capacitance Change Within the specified tolerance  Change Q/D.F. 30pFmin.: Q≥1000 R7: 0.125max amplitude of 1.5mm, the frequency being varied uniformly the approximate limits of 10 and 2000Hz. The frequency rate of 10 to 2000Hz and return to 10Hz, should be applied for inapproximately 20 minutes. This motion should be applied for items in each 3 mutually perpendicular directions (total of 3 mutually perpendicular directions (total of 3 mutually perpendicular directions total of 3 mutually perpendicular directions in the following table.  Resistance to Soldering Heat specifications in the following table.	Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).    Condition   Co						
Vibration   Appearance   No defects or abnormalities   Solder the capacitor to the test jig (glass epoxy board) in the manner and under the same conditions as (18). The capacitor change   O/D.F.   30pFmin.: Q≥1000   R7: 0.125max   amplitude of 1.5mm, the frequency being varied uniformly the approximate limits of 10 and 2000Hz. The frequency rate of 10 to 2000Hz and return to 10Hz, should be applied for inapproximately 20 minutes. This motion should be applied for items in each 3 mutually perpendicular directions (total of 3 mutually perpendicular directions in the following table.   Immerse the capacitor in a eutectic solder solution at 260± 10±1 seconds. Set at room temperature for 24±2 hours, the seconds of the description of the test jig (glass epoxy board) in the manner and under the same conditions as (18). The capacitor in the test jig (glass epoxy board) in the manner and under the same conditions as (18). The capacitor having a should be subjected to a simple harmonic motion having a amplitude of 1.5mm, the frequency being varied uniformly the approximate limits of 10 and 2000Hz. The frequency rate of 10 to 2000Hz and return to 10Hz, should be applied for inapproximately 20 minutes. This motion should be applied for inapproximately 20 minutes. This motion should be applied for inapproximately 20 minutes. This motion should be applied for inapproximately 20 minutes. This motion should be applied for inapproximately 20 minutes. The frequency being varied uniformly the approximate limits of 10 and 2000Hz. The frequency provided in the pr	Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).    Condition   Cond			Insulation	More than $10,000M\Omega$ or $500\Omega \cdot F$	R7: More than 1000MΩ or 50Ω •F	
Capacitance Change   Within the specified tolerance   Mithin the specified tolerance   Change   Mithin the specified tolerance   Mithin the specified tolerance   Mithin the specified tolerance   Mithin the specified tolerance   Should be subjected to a simple harmonic motion having a amplitude of 1.5mm, the frequency being varied uniformly to 20pc   Should be subjected to a simple harmonic motion having a amplitude of 1.5mm, the frequency being varied uniformly to 20pc   Should be approximate limits of 10 and 2000Hz. The frequency rate   10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for items in each 3 mutually perpendicular directions (total of 3 mutually perpendicular directions) (total of 3 mutually perpend	manner and under the same conditions as (18). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).    Minute   Manage   Mana			Resistance	(Whichever is smaller)	(Whichever is smaller)	
Change  Q/D.F.  30pFmin.: Q≥1000  R7: 0.125max  amplitude of 1.5mm, the frequency being varied uniformly the approximate limits of 10 and 2000Hz. The frequency rate in approximately 20 minutes. This motion should be applied for approximately 20 minutes. This motion should be applied for the measured and observed characteristics should satisfy the specifications in the following table.  R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)	should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).    Mathematical R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)   Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.    R7: 0.125max   Perform a heat treatment at 150+0/-10 °C for one hour and then set   Perform a heat treatment at 150+0/-10 °C for one hour and then set	11	Vibration	Appearance	No defects or abnormalities	•	Solder the capacitor to the test jig (glass epoxy board) in the same
Change  Q/D.F.  30pFmin.: Q≥1000  R7: 0.125max  amplitude of 1.5mm, the frequency being varied uniformly the approximate limits of 10 and 2000Hz. The frequency rate in approximately 20 minutes. This motion should be applied for approximately 20 minutes. This motion should be applied for the measured and observed characteristics should satisfy the specifications in the following table.  R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω ⋅ F (Whichever is smaller)	should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  (Whichever is smaller)  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Initial measurement for high dielectric constant type  Perform a heat treatment at 150+0/-10 °C for one hour and then set			Capacitance	Within the specified tolerance		manner and under the same conditions as (18). The capacitor
Q/D.F.       30pFmin.: Q≥1000 30pFmax.: Q≥400+20C C: Nominal Capacitance(pF)       R7: 0.125max       amplitude of 1.5mm, the frequency being varied uniformly the approximate limits of 10 and 2000Hz. The frequency rare 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for items in each 3 mutually perpendicular directions (total of 3 (Whichever is smaller))         12       Resistance to Soldering Heat       The measured and observed characteristics should satisfy the specifications in the following table.       Immerse the capacitor in a eutectic solder solution at 260-3 (10±1 seconds. Set at room temperature for 24±2 hours, the specifications in the following table.	R7: 0.125max  amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  (Whichever is smaller)  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Initial measurement for high dielectric constant type  R7: 0.125max  Perform a heat treatment at 150+0/-10 °C for one hour and then set	- 1					
30pFmax.: Q ≥ 400+20C C: Nominal Capacitance(pF)  Insulation Resistance  More than 10,000MΩ or 500Ω • F (Whichever is smaller)  The measured and observed characteristics should satisfy the Soldering Heat	the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  (Whichever is smaller)  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Initial measurement for high dielectric constant type  Perform a heat treatment at 150+0/-10 °C for one hour and then set				30pFmin. : Q≧1000	R7: 0.125max	
C: Nominal Capacitance(pF)  10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for approximately 20 minutes. This motion should be applied for items in each 3 mutually perpendicular directions (total of 3 (Whichever is smaller))  12 Resistance to Soldering Heat Specifications in the following table.  13 The measured and observed characteristics should satisfy the specifications in the following table.  14 The measured and observed characteristics should satisfy the specifications in the following table.	10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12  20Ω · F  R7: More than 1000MΩ or 50Ω · F  (Whichever is smaller)  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  R7: 0.125max  10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.			I .	1		
approximately 20 minutes. This motion should be applied fittens in each 3 mutually perpendicular directions (total of 3 mutually perpendicular directions).  Resistance to Soldering Heat specifications in the following table.  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω · F (Whichever is smaller)  R8: More than 1000MΩ or 50Ω · F (Whichever is smaller)	approximately 20 minutes. This motion should be applied for 12  20Ω · F R7: More than 1000MΩ or 50Ω · F (Whichever is smaller)  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  R7: 0.125max  Perform a heat treatment at 150+0/-10 °C for one hour and then set				30pFmax.: Q ≥400+20C		Ithe approximate limits of 10 and 2000Hz. The frequency range, from
Insulation Resistance (Whichever is smaller)  R7: More than 1000ΜΩ or 50Ω • F (Whichever is smaller)  R7: More than 1000ΜΩ or 50Ω • F (Whichever is smaller)  R7: More than 1000ΜΩ or 50Ω • F (Whichever is smaller)  R7: More than 1000ΜΩ or 50Ω • F (Whichever is smaller)  R7: More than 1000ΜΩ or 50Ω • F (Whichever is smaller)  R7: More than 1000ΜΩ or 50Ω • F (Whichever is smaller)  R7: More than 1000ΜΩ or 50Ω • F (Whichever is smaller)  R8: More than 1000ΜΩ or 50Ω • F (Whichever is smaller)  R8: More than 1000ΜΩ or 50Ω • F (Whichever is smaller)  R8: More than 1000ΜΩ or 50Ω • F (Whichever is smaller)  R8: More than 1000ΜΩ or 50Ω • F (Whichever is smaller)  R8: More than 1000ΜΩ or 50Ω • F (Whichever is smaller)	R7: More than 1000MΩ or 50Ω · F items in each 3 mutually perpendicular directions (total of 36 times).    R7: More than 1000MΩ or 50Ω · F items in each 3 mutually perpendicular directions (total of 36 times).    Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.    R7: 0.125max   Perform a heat treatment at 150+0/-10 °C for one hour and then set				· ·		
Resistance (Whichever is smaller) (Whichever is smaller)  12 Resistance to Soldering Heat specifications in the following table.  (Whichever is smaller) Immerse the capacitor in a eutectic solder solution at 260 ± 10±1 seconds. Set at room temperature for 24 ± 2 hours, the specifications in the following table.	(Whichever is smaller)  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Initial measurement for high dielectric constant type  R7: 0.125max  Perform a heat treatment at 150+0/-10 °C for one hour and then set				· ·		10 to 2000Hz and return to 10Hz, should be traversed in
12 Resistance to Soldering Heat The measured and observed characteristics should satisfy the specifications in the following table.  Immerse the capacitor in a eutectic solder solution at 260 ± 10±1 seconds. Set at room temperature for 24 ± 2 hours, the specifications in the following table.	Immerse the capacitor in a eutectic solder solution at 260±5°C for ng table.  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Ince  Initial measurement for high dielectric constant type  R7: 0.125max  Perform a heat treatment at 150+0/-10 °C for one hour and then set			Insulation	C: Nominal Capacitance(pF)	R7: More than 1000MO or 500 v.E.	10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12
Soldering Heat specifications in the following table. 10±1 seconds. Set at room temperature for 24±2 hours, the	ng table.  10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Initial measurement for high dielectric constant type  R7: 0.125max  Perform a heat treatment at 150+0/-10 °C for one hour and then set				C: Nominal Capacitance(pF)  More than $10,000M\Omega$ or $500\Omega$ · F		10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12
Soldering Heat specifications in the following table.  10±1 seconds. Set at room temperature for 24±2 hours, the	ng table.  10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Initial measurement for high dielectric constant type  R7: 0.125max  Perform a heat treatment at 150+0/-10 °C for one hour and then set				C: Nominal Capacitance(pF)  More than $10,000M\Omega$ or $500\Omega$ · F		10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12
Soldering Heat specifications in the following table. 10±1 seconds. Set at room temperature for 24±2 hours, the	ng table.  10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Initial measurement for high dielectric constant type  R7: 0.125max  Perform a heat treatment at 150+0/-10 °C for one hour and then set				C: Nominal Capacitance(pF)  More than $10,000M\Omega$ or $500\Omega$ · F		10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12
	measure.  Ince Initial measurement for high dielectric constant type  R7: 0.125max Perform a heat treatment at 150+0/-10 °C for one hour and then set	10	Posieta-22 4		C: Nominal Capacitance(pF)  More than $10,000M\Omega$ or $500\Omega$ ·F (Whichever is smaller)	(Whichever is smaller)	10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).
Language INO marking detects	rice  Initial measurement for high dielectric constant type  R7: 0.125max  Perform a heat treatment at 150+0/-10 °C for one hour and then set	12		Resistance	C: Nominal Capacitance(pF)  More than $10,000M\Omega$ or $500\Omega$ ·F (Whichever is smaller)  The measured and observed characterists	(Whichever is smaller)	10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  Immerse the capacitor in a eutectic solder solution at 260±5°C for
	Perform a heat treatment at 150+0/-10 °C for one hour and then set	12		Resistance	C: Nominal Capacitance(pF)  More than $10,000M\Omega$ or $500\Omega$ · F  (Whichever is smaller)  The measured and observed charac specifications in the following table.	(Whichever is smaller)	10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then
	R7: 0.125max Perform a heat treatment at 150+0/-10 °C for one hour and then set	12		Resistance	C: Nominal Capacitance(pF)  More than 10,000MΩ or 500Ω • F (Whichever is smaller)  The measured and observed charac specifications in the following table. No marking defects	(Whichever is smaller)	10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then
		12		Appearance Capacitance	C: Nominal Capacitance(pF)  More than $10,000M\Omega$ or $500\Omega$ · F  (Whichever is smaller)  The measured and observed charac specifications in the following table.	(Whichever is smaller)	10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.
	for 24±2 hours at room temperature.	12		Appearance Capacitance Change	C: Nominal Capacitance(pF)  More than 10,000MΩ or 500Ω • F (Whichever is smaller)  The measured and observed charac specifications in the following table.  No marking defects  Within the specified tolerance	(Whichever is smaller) teristics should satisfy the	10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Initial measurement for high dielectric constant type
30pFmax.: Q ≥400+20C for 24±2 hours at room temperature.		12		Appearance Capacitance Change	C: Nominal Capacitance(pF)  More than 10,000MΩ or 500Ω • F (Whichever is smaller)  The measured and observed charac specifications in the following table.  No marking defects  Within the specified tolerance	(Whichever is smaller) teristics should satisfy the	10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Initial measurement for high dielectric constant type
C: Nominal Capacitance(pF)  Perform the initial measurement.	e(pF) Perform the initial measurement.	12		Appearance Capacitance Change	C: Nominal Capacitance(pF)  More than 10,000MΩ or 500Ω •F (Whichever is smaller)  The measured and observed charac specifications in the following table.  No marking defects  Within the specified tolerance	(Whichever is smaller) teristics should satisfy the	10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Initial measurement for high dielectric constant type Perform a heat treatment at 150+0/-10 °C for one hour and then set
		12		Appearance Capacitance Change	C: Nominal Capacitance(pF)  More than 10,000MΩ or 500Ω • F (Whichever is smaller)  The measured and observed charac specifications in the following table.  No marking defects  Within the specified tolerance  30pFmin. : Q≥1000  30pFmax.: Q≥400+20C	(Whichever is smaller) teristics should satisfy the	10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Initial measurement for high dielectric constant type Perform a heat treatment at 150+0/-10 °C for one hour and then set for 24±2 hours at room temperature.
Insulation More than $10,000M\Omega$ or $500\Omega \cdot F$ R7: More than $1000M\Omega$ or $50\Omega \cdot F$	00Ω · F R7: More than 1000MΩ or 50Ω · F	12		Appearance Capacitance Change	C: Nominal Capacitance(pF)  More than 10,000MΩ or 500Ω • F (Whichever is smaller)  The measured and observed charac specifications in the following table.  No marking defects  Within the specified tolerance  30pFmin. : Q≥1000  30pFmax.: Q≥400+20C	(Whichever is smaller) teristics should satisfy the	10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Initial measurement for high dielectric constant type Perform a heat treatment at 150+0/-10 °C for one hour and then set for 24±2 hours at room temperature.
		12		Appearance Capacitance Change Q/D.F.	C: Nominal Capacitance(pF)  More than 10,000MΩ or 500Ω • F (Whichever is smaller)  The measured and observed charac specifications in the following table.  No marking defects  Within the specified tolerance  30pFmin. : Q≥1000  30pFmax.: Q≥400+20C  C: Nominal Capacitance(pF)	(Whichever is smaller) teristics should satisfy the	10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Initial measurement for high dielectric constant type Perform a heat treatment at 150+0/-10 °C for one hour and then set for 24±2 hours at room temperature.  Perform the initial measurement.
Resistance (Whichever is smaller) (Whichever is smaller)	(Whichever is smaller)	112		Appearance Capacitance Change Q/D.F.	C: Nominal Capacitance(pF)  More than $10,000M\Omega$ or $500\Omega \cdot F$ (Whichever is smaller)  The measured and observed charac specifications in the following table.  No marking defects  Within the specified tolerance $30pFmin.: Q \ge 1000$ $30pFmax.: Q \ge 400+20C$ C: Nominal Capacitance(pF)	(Whichever is smaller)  teristics should satisfy the  R7: 0.125max  R7: More than 1000MΩ or 50Ω • F	10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Initial measurement for high dielectric constant type Perform a heat treatment at 150+0/-10 °C for one hour and then set for 24±2 hours at room temperature.  Perform the initial measurement.
	1 I	12		Appearance Capacitance Change Q/D.F.	C: Nominal Capacitance(pF)  More than $10,000M\Omega$ or $500\Omega \cdot F$ (Whichever is smaller)  The measured and observed charac specifications in the following table.  No marking defects  Within the specified tolerance $30pFmin.: Q \ge 1000$ $30pFmax.: Q \ge 400+20C$ C: Nominal Capacitance(pF)	(Whichever is smaller)  teristics should satisfy the  R7: 0.125max  R7: More than 1000MΩ or 50Ω • F	10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).  Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure.  Initial measurement for high dielectric constant type Perform a heat treatment at 150+0/-10 °C for one hour and then set for 24±2 hours at room temperature.  Perform the initial measurement.

			Speci	ifications.							
		00 Test Item	Temperature Compensating Type	High Dielectric Type			AEC-Q20	00 Test M	/lethod		
3 Therm	nal Shoo	ck	The measured and observed characteristications in the following table.	cteristics shall satisfy the	-		he supporting ji as (18). Perforn	-			
		Appearance	No marking defects		-		nts listed in the			-	110
		Capacitance	Within ±2.5% or ±0.25pF	R7: Within ±10.0%	transfer tim				, (		
		Change	(Whichever is larger)		Set for 24±	£2 hours at	t room temperat	ure, then	n measure	Э.	
		Q/D.F.	30pFmin. : Q≧1000	R7: 0.125max	Ste	en	1		2		7
			30pFmax.: Q ≧400+20C		Temp		-40+0/-3		 105+3/- For ΔC/I	0	1
			C: Nominal Capacitance(pF)		(°C)		(For ΔC/R7)	(F	For ∆C/I	R7)	
		Insulation	More than 10,000MΩ or 500Ω • F	R7: More than 1000MΩ or 50Ω •F	Time (min.) 15±3 15±3						
		Resistance	(Whichever is smaller)	(Whichever is smaller)							
			(**************************************	(**************************************	·Initial mea	asurement	for high dielect	ric const	ant type		
					Initial measurement for high dielectric constant type  Perform a heat treatment at 150+0/-10 for one hour and then set						
					for 24±2 ho	ours at roo	om temperature.				
					Perform the initial measurement.						
4 ESD		Appearance	No marking defects		Per AEC-Q						
		Capacitance Change	Within the specified tolerance		Voltage se	etting level	I: 2KV				
		Q/D.F.	30pFmin. : Q≧1000	R7: 0.125max	=						
			30pFmax.: Q ≧400+20C								
			C: Nominal Capacitance(pF)								
					_						
		Insulation	More than 10,000MΩ or 500Ω • F	R7: More than 1000MΩ or 50Ω •F							
5 Solder	rahility	Resistance	(Whichever is smaller)  95% of the terminations is to be sold	(Whichever is smaller)	(a) Probact	t at 155°C	for 4 hours. Aft	er preha	ating imp	neree the	۵
Joolaei	iability			dered every and community.			ution of ethanol				
					-		in weight propo				
					eutectic	solder sol	lution for 5+0/-0	.5 secon	ds at 235	±5℃.	
							I into steam agii	-			
					1	erieating, i	immerse the cap	Jacitoi III	i a solulio	// UI	
					ethanol(	(JIS-K-810	01) and rosin (Jl	S-K-590:	2) (25% r	osin in w	veiaht .
							01) and rosin (Ji				eight /
					propotio		se in eutectic s				veight
					propotio	on). Immer	se in eutectic s				veight
					propotio seconds (c) Should	on). Immer s at 235±5 be placed	rse in eutectic so °C.	older solu	ution for 5	5+0/-0.5 minutes.	-
					propotio seconds (c) Should After pre	on). Immer s at 235±5 be placed eheating, i	rse in eutectic so °C. I into steam agir immerse the cap	older solu ng for 8 h	nours±15	minutes.	
					(c) Should After preethanol(	be placed eheating, i	rse in eutectic so of the control of	ng for 8 h pacitor in	nours±15 nours±15 nours±17 nours±15 nours±17	minutes.	veight
					(c) Should After preethanol(	be placed eheating, i (JIS-K-810	rse in eutectic so °C. I into steam agir immerse the cap	ng for 8 h pacitor in	nours±15 nours±15 nours±17 nours±15 nours±17	minutes.	veight
					(c) Should After preethanol(propotio	be placed eheating, i (JIS-K-810	rse in eutectic so of the control of	ng for 8 h pacitor in	nours±15 nours±15 nours±17 nours±15 nours±17	minutes.	veight
6 Electri		Appearance	No defects or abnormalities		(c) Should After preethanol(propotio at 260±	be placed eheating, i (JIS-K-810 on). Immer 5°C.	se in eutectic so c. I into steam agir immerse the cap on and rosin (JI se in eutectic so	ng for 8 h pacitor in IS-K-590:	nours±15 nours±15 nours±15 nours±15 nours±15 nours nours±15 nours nours nours nours	minutes. on of rosin in w 120±5 se	veight
Chata	acteri-	Capacitance	No defects or abnormalities Within the specified tolerance		(c) Should After preethanol(propotio at 260±.	be placed eheating, i (JIS-K-810 on). Immer .5°C.	se in eutectic so c. I into steam agir immerse the cap of) and rosin (JI se in eutectic so on.F. should be n	ng for 8 h pacitor in IS-K-590 older solu	nours±15 nours±15 nours±15 nours±15 nours±15 nours nours±15 nours nours nours nours	minutes. on of rosin in w 120±5 se	veight
	acteri-	Capacitance Change	Within the specified tolerance	D7 : 0.425 may	(c) Should After preethanol(propotio at 260±.	be placed eheating, i (JIS-K-810 on). Immer .5°C.	se in eutectic so c. I into steam agir immerse the cap on and rosin (JI se in eutectic so	ng for 8 h pacitor in IS-K-590 older solu	nours±15 nours±15 nours±15 nours±15 nours±15 nours nours±15 nours nours nours nours	minutes. on of rosin in w 120±5 se	veight
Chata	acteri-	Capacitance	Within the specified tolerance  30pFmin. : Q≧1000	R7 : 0.125max.	(c) Should After preethanol(propotio at 260±.	on). Immer s at 235±5 be placed eheating, i (JIS-K-810 on). Immer 5°C. eection. itance/Q/E and voltag	se in eutectic so o'C.  I into steam agir immerse the cap of ) and rosin (Ji se in eutectic so o.F. should be not ge shown in the	ng for 8 h pacitor in IS-K-590 blder solu neasured table.	nours±15 nours±15 nours±15 nours±15 nours±15 nours nours±15 nours nours nours nours	minutes. on of rosin in w 120±5 se	veight
Chata	acteri-	Capacitance Change	Within the specified tolerance	R7 : 0.125max.	(c) Should After preethanol(propotio at 260±.	on). Immer s at 235±5 be placed eheating, i (JIS-K-810 on). Immer 5°C. eection. itance/Q/E and voltag	se in eutectic so "C.  I into steam agin immerse the cap of the ca	ng for 8 h pacitor in S-K-590; blder solu	nours±15 a a solution for 1 d at 25°C :	minutes. on of rosin in w 120±5 se	veight
Chata	acteri-	Capacitance Change	Within the specified tolerance  30pFmin.: Q≥1000  30pFmax.: Q≥400+20C	R7 : 0.125max.	(c) Should After preethanol(propotio at 260±.	be placed eheating, it (JIS-K-810 on). Immer 5°C.  Dection. itance/Q/E and voltage ature Common on the common of t	se in eutectic so of the cap again and the cap again and the cap and the cap again again and the cap again again and the cap again a	ng for 8 h pacitor in S-K-590; blder solu	nours±15 nours±15 nours±15 nours±15 nours±15 nours nours±15 nours nours nours nours	minutes. on of rosin in w 120±5 se	veight
Chata	acteri-	Capacitance Change	Within the specified tolerance  30pFmin.: Q≥1000  30pFmax.: Q≥400+20C	R7 : 0.125max.	propotion seconds  (c) Should I After preethanol(propotion at 260±5  Visual insport The capacifrequency at 11 Temperature 11 Temperature 11 Temperature 11 Temperature 12 Temperature 11 Temperature 11 Temperature 12 T	be placed eheating, it (JIS-K-810 on). Immer 5°C.  Dection. itance/Q/E and voltage ature Common on the common of t	se in eutectic so of the capensating Type of the cape	ng for 8 h pacitor in IS-K-590 plder solu neasured table.	nours±15 a a solution for 1 d at 25°C :	minutes. on of rosin in w 120±5 se  at the	veight
Chata	acteri-	Capacitance Change	Within the specified tolerance  30pFmin.: Q≥1000  30pFmax.: Q≥400+20C	R7 : 0.125max.	(c) Should After preethanol(propotio at 260±.  Visual insporte capacifrequency at 11ter	be placed eheating, i (JIS-K-81( )cn). Immer 5°C.  be placed eheating, i (JIS-K-81( )cn). Immer 5°C.  bection. itance/Q/E and voltag ature Com Cham	se in eutectic so of the capensating Type of the cape	ng for 8 h pacitor in IS-K-590 plotted table.	nours±15 n a solution for 1 a solution for 1 at 25°C :	minutes. on of rosin in w 120±5 se  at the	veight
Chata	acteri-	Capacitance Change	Within the specified tolerance  30pFmin.: Q≥1000  30pFmax.: Q≥400+20C	R7: 0.125max.	propotion seconds  (c) Should After preethanol(propotion at 260±!  Visual insport frequency at 11ter	be placed eheating, is (JIS-K-810 on). Immer 5°C.  be ction. itance/Q/E and voltage ature Com Cham	se in eutectic so of the capensating Type  1.	ng for 8 h pacitor in IS-K-590 plotted table.	nours±15 a a solution for 1 a solution for 1 at 25°C a c>100 $\pm$ 0.1	minutes. on of rosin in w 120±5 se  at the	veight
Chata	acteri-	Capacitance Change	Within the specified tolerance  30pFmin.: Q≥1000  30pFmax.: Q≥400+20C	R7: 0.125max.	propotion seconds  (c) Should After preethanol(propotion at 260±!  Visual insportion frequency at 11ter	be placed eheating, is at 235±5 be placed eheating, is (JIS-K-810). Immer 5°C.  bection. itance/Q/C and voltag ature Com Cham	se in eutectic service.  It into steam aging immerse the capable of the capable	ng for 8 h pacitor in IS-K-590 plotted table.	nours±15 a a solution for 1 a solution for 1 at 25°C a c>100 $\pm$ 0.1	minutes. on of rosin in w 120±5 se  at the	veight
Chata	acteri-	Capacitance Change	Within the specified tolerance  30pFmin.: Q≥1000  30pFmax.: Q≥400+20C	R7 : 0.125max.	propotion seconds  (c) Should I After preethanol(propotion at 260±5  Visual insportion frequency at 11ter F F (2) High Die	be placed eheating, i (JIS-K-81() on). Immer 5°C.  bection. itance/Q/C and voltag ature Com Cha m Voltage electric Cc Char.	se in eutectic so in eutectic so se in eutectic so se in eutectic so in eutectic so se in eutectic so	ng for 8 h pacitor in S-K-590; blder solu neasured table.	ution for 5 nours±15 n a solution 2) (25% r ution for 1 d at 25°C $\approx$ C>100 1±0.1 1±0.2 $\approx$ 0 $\mu$ F	minutes. on of rosin in w 120±5 se  at the	veight
Chata	acteri-	Capacitance Change	Within the specified tolerance  30pFmin.: Q≥1000  30pFmax.: Q≥400+20C	R7: 0.125max.	propotion seconds  (c) Should I After preethanol(propotion at 260±8.  Visual insportion frequency at 11ter F (2) High Die	be placed eheating, is at 235±5 be placed eheating, is (JIS-K-810). Immer 5°C.  bection. itance/Q/C and voltag ature Com Cham Trequency Voltage	se in eutectic so in eutectic so se in eutectic so in eutectic so se in eutectic so in eutec	ng for 8 h pacitor in S-K-590: blder solu  neasured table.  pF  Hz  /rms	nours±15 a a solution for 1 a solution	minutes. on of rosin in w 120±5 se  at the  OpF  kHz /rms	veight conds
Chata	acteri-	Capacitance Change	Within the specified tolerance  30pFmin.: Q≥1000  30pFmax.: Q≥400+20C	R7: 0.125max.	propotion seconds  (c) Should I After preethanol(propotion at 260±5  Visual insport frequency at 11tem Free Free Free Free Free Free Free Fr	be placed eheating, i (JIS-K-810 on). Immer 5°C. bection. itance/Q/L and voltage ature Com Cha m Frequency Voltage char. equency	see in eutectic service. See in eutectic service. Into steam again immerse the capped of the capped	ng for 8 h pacitor in S-K-590i plder solu neasured table.  pF Hz (100 i	nours±15 n a solution for 1 n a solution for 1 n a solution for 1 n at 25°C $\approx$ C>100 1 ± 0. 1 1 ± 0. 2 $\approx$ 1 kHz	minutes. on of osin in w 120±5 se  at the  OpF kHz /rms	veight sconds
Chata	acteri-	Capacitance Change	Within the specified tolerance  30pFmin.: Q≥1000  30pFmax.: Q≥400+20C	R7: 0.125max.	propotion seconds  (c) Should I After preethanol(propotion at 260±5  Visual insport frequency at 11tem Free Free Free Free Free Free Free Fr	be placed eheating, is at 235±5 be placed eheating, is (JIS-K-810). Immer 5°C.  bection. itance/Q/C and voltag ature Com Cham Trequency Voltage	se in eutectic so in eutectic so se in eutectic so in eutectic so se in eutectic so in eutec	ng for 8 h pacitor in S-K-590: blder solu  neasured table.  pF  Hz  /rms	nours±15 n a solution for 1 n a solution for 1 n a solution for 1 n at 25°C $\approx$ C>100 1 ± 0. 1 1 ± 0. 2 $\approx$ 1 kHz	minutes. on of rosin in w 120±5 se  at the  OpF  kHz /rms	veight econds
Chata	acteri-	Capacitance Change Q/D.F.	Within the specified tolerance  30pFmin.: Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF)		visual insp The capaci frequency a  (2) High Die	be placed eheating, it (JIS-K-810 on). Immer s at 235±5 be placed eheating, it (JIS-K-810 on). Immer 5°C. bection. itance/Q/L and voltage ature Com of requency Voltage electric Co on the control of the	se in eutectic so of the control of	ng for 8 h pacitor in S-K-590; blder solu neasured table.  c ≤ 10 (100 r 1±0.	ution for 5 nours±15 n a solution 2) (25% r ution for 1 d at 25°C at 2	minutes. on of rosin in w 120±5 se  at the  OpF kHz /rms  10µF  120±2 0.5±0.	veight conds  < C  24Hz
Chata	acteri-	Capacitance Change Q/D.F.	Within the specified tolerance  30pFmin.: Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF)  More than 100,000MΩ or 1000Ω•F	R7: More than 1000MΩ or 50Ω •F	propotion seconds  (c) Should After preethanol(propotion at 260±4  Visual insportion at 260±4  (1) Temperation (1) Temperation (2) High Dieler Freethanol(propotion at 260±4  The insulation freethanol (2) High Dieler Freethanol (2) High D	be placed eheating, i (JIS-K-810 on). Immer s at 235±5 be placed eheating, i (JIS-K-810 on). Immer 5°C.  bection. itance/Q/L and voltage ature Com Cham frequency Voltage electric Co Char. equency oltage	se in eutectic se in	ng for 8 h pacitor in S-K-590; blder solu neasured table.  c ≤ 10 (100 r 1±0.:	nours±15 n a solution for 1 n a	minutes. on of rosin in w 120±5 se  at the  OpF kHz /rms  10µF  120±2 0.5±0.	veight conds  < C  24Hz
Chata	acteri-	Capacitance Change Q/D.F.  Insulation Resistance	Within the specified tolerance  30pFmin.: Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF)		propotion seconds  (c) Should I After preethanol(propotion at 260±5  Visual insportion frequency at 11-tem Free Free Free Free Free Free Free Fr	be placed eheating, i (JIS-K-810). Immer 5°C.  bection. Immer 5°C.  bection. itance/Q/L and voltage ature Com Cha m Frequency Voltage equency oltage the rated the rated of the control of	see in eutectic service. See in eutectic service. Into steam again immerse the capped of the capped	ng for 8 h pacitor in S-K-590; blder solu neasured table.  c ≤ 10 (100 r 1±0.:	nours±15 n a solution for 1 n a	minutes. on of rosin in w 120±5 se  at the  OpF kHz /rms  10µF  120±2 0.5±0.	veight conds  < C  24Hz
Chata	acteri-	Capacitance Change Q/D.F.  Insulation Resistance 25°C	Within the specified tolerance $30pFmin.: Q \geqq 1000$ $30pFmax.: Q \geqq 400+20C$ C: Nominal Capacitance(pF)  More than $100,000M\Omega$ or $1000\Omega \cdot F$ (Whichever is smaller)	R7: More than 1000M $\Omega$ or 50 $\Omega$ •F (Whichever is smaller)	propotion seconds  (c) Should After preethanol(propotion at 260±5  Visual insportion at 260±5  (1) Temperation (1) Temperation (2) High Dieler Freethanol(propotion at 260±5)  (2) High Dieler Freethanol(propotion at 260±5)  Item Freethanol(propotion at 260±5)  The insulation at 260±50  The insulation at	be placed eheating, i (JIS-K-810). Immer 5°C.  bection. Immer 5°C.  bection. itance/Q/L and voltage ature Com Cha m Frequency Voltage equency oltage the rated the rated of the control of	see in eutectic service. See in eutectic service. Into steam again immerse the capped of the capped	ng for 8 h pacitor in S-K-590; blder solu neasured table.  c ≤ 10 (100 r 1±0.:	nours±15 n a solution for 1 n a	minutes. on of rosin in w 120±5 se  at the  OpF kHz /rms  10µF  120±2 0.5±0.	veight conds  < C  24Hz
Chata	acteri-	Capacitance Change Q/D.F.  Insulation Resistance	Within the specified tolerance  30pFmin.: Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF)  More than 100,000MΩ or 1000Ω•F	R7: More than 1000MΩ or 50Ω •F	propotion seconds  (c) Should I After preethanol(propotion at 260±5  Visual insportion frequency at 11-tem Free Free Free Free Free Free Free Fr	be placed eheating, i (JIS-K-810). Immer 5°C.  bection. Immer 5°C.  bection. itance/Q/L and voltage ature Com Cha m Frequency Voltage equency oltage the rated the rated of the control of	see in eutectic service. See in eutectic service. Into steam again immerse the capped of the capped	ng for 8 h pacitor in S-K-590; blder solu neasured table.  c ≤ 10 (100 r 1±0.:	nours±15 n a solution for 1 n a	minutes. on of rosin in w 120±5 se  at the  OpF kHz /rms  10µF  120±2 0.5±0.	veight conds  < C  24Hz
Chata	acteri-	Capacitance Change Q/D.F.  Insulation Resistance 25°C Insulation	Within the specified tolerance $30pFmin.: Q \geqq 1000$ $30pFmax.: Q \geqq 400+20C$ C: Nominal Capacitance(pF)  More than $100,000M\Omega$ or $1000\Omega \cdot F$ (Whichever is smaller)  More than $10,000M\Omega$ or $100\Omega \cdot F$	R7: More than $1000M\Omega$ or $50\Omega \cdot F$ (Whichever is smaller)	propotion seconds  (c) Should I After preethanol(propotion at 260±5  Visual insportion frequency at 11-tem Free Free Free Free Free Free Free Fr	be placed eheating, i (JIS-K-810). Immer 5°C.  bection. Immer 5°C.  bection. itance/Q/L and voltage ature Com Cha m Frequency Voltage equency oltage the rated the rated of the control of	see in eutectic service. See in eutectic service. Into steam again immerse the capped of the capped	ng for 8 h pacitor in S-K-590; blder solu neasured table.  c ≤ 10 (100 r 1±0.:	nours±15 n a solution for 1 n a	minutes. on of rosin in w 120±5 se  at the  OpF kHz /rms  10µF  120±2 0.5±0.	veight conds  < C  24Hz
Chata	acteri-	Capacitance Change Q/D.F.  Insulation Resistance 25°C Insulation Resistance	Within the specified tolerance $30pFmin.: Q \geqq 1000$ $30pFmax.: Q \geqq 400+20C$ C: Nominal Capacitance(pF)  More than $100,000M\Omega$ or $1000\Omega \cdot F$ (Whichever is smaller)  More than $10,000M\Omega$ or $100\Omega \cdot F$	R7: More than $1000M\Omega$ or $50\Omega \cdot F$ (Whichever is smaller)	propotion seconds  (c) Should I After preethanol(propotion at 260±5  Visual insportion frequency at 11-tem Free Free Free Free Free Free Free Fr	be placed eheating, i (JIS-K-810). Immer 5°C.  bection. Immer 5°C.  bection. itance/Q/L and voltage ature Com Cha m Frequency Voltage equency oltage the rated the rated of the control of	see in eutectic service. See in eutectic service. Into steam again immerse the capped of the capped	ng for 8 h pacitor in S-K-590; blder solu neasured table.  c ≤ 10 (100 r 1±0.:	nours±15 n a solution for 1 n a	minutes. on of rosin in w 120±5 se  at the  OpF kHz /rms  10µF  120±2 0.5±0.	veight conds  < C  24Hz
Chata	acteri-	Capacitance Change Q/D.F.  Insulation Resistance 25°C Insulation Resistance 125°C Dielectric	Within the specified tolerance $30pFmin.: Q \geqq 1000$ $30pFmax.: Q \geqq 400+20C$ C: Nominal Capacitance(pF)  More than $100,000M\Omega$ or $1000\Omega \cdot F$ (Whichever is smaller)  More than $10,000M\Omega$ or $100\Omega \cdot F$	R7: More than $1000M\Omega$ or $50\Omega \cdot F$ (Whichever is smaller)	propotion seconds  (c) Should   After preenthanol( propotion at 260±!  Visual insportion frequency at   After preenthanol( propotion at 260±!  Visual insportion frequency at   After preenthanol( propotion at 260±!  (1) Temperature   Free preenthanol( propotion at 260±!  (2) High Die   After preenthanol( propotion at 260±!  (2) High Die   After preenthanol( propotion at 260±!  The insulate exceeding the within 1 minus   After preenthanol( propotion at 260±!  The insulate exceeding the within 1 minus   After preenthanol( propotion at 260±!  No failure set   After preenthanol( propotion	be placed eheating, i (JIS-K-810 on). Immer s at 235±5 be placed eheating, i (JIS-K-810 on). Immer 5°C.  Dection. itance/Q/E and voltage ature Com Cham of Char. C	se in eutectic service.  I into steam aginimmerse the caport of the cap	ng for 8 h pacitor in S-K-590: older solutions of the solution	nours±15 a a solution for 1 a solution for 1 a solution for 1 a solution for 1 at 25°C; at 2	minutes. on of rosin in w 120±5 see  at the  OpF kHz /rms  10µF 120±2 0.5±0.  DC voltage	veight conds  < C 24Hz IVrms ge not
Chata	acteri-	Capacitance Change Q/D.F.  Insulation Resistance 25°C Insulation Resistance 125°C	Within the specified tolerance  30pFmin.: Q≥1000 30pFmax.: Q≥400+20C C: Nominal Capacitance(pF)  More than 100,000MΩ or 1000Ω•F (Whichever is smaller)  More than 10,000MΩ or 100Ω•F (Whichever is smaller)	R7: More than $1000M\Omega$ or $50\Omega \cdot F$ (Whichever is smaller)	propotion seconds  (c) Should   After preethanol( propotion at 260±!  Visual insport   The capacities   After preethanol( propotion at 260±!  Visual insport   The capacities   After preethanol( propotion at 260±!  (1)Temperative   The insulaties   After preethanol( pree	be placed eheating, is (JIS-K-810 on). Immer s at 235±5 be placed eheating, is (JIS-K-810 on). Immer 5°C.  Dection. itance/Q/E and voltage ature Common of the common of t	se in eutectic so of the capensating Type  C≤1000  1±0.1kHz  0.5±0.1Vrms  ance should be to the capensating Type  C≤10 \( \pi \)  1±0.1kHz  0.5±0.1Vrms	ng for 8 h pacitor in S-K-590: older solutions. The solution of the solution o	ution for $\pm$ nours±15 n a solution $\pm$ 2) (25% r ution for $\pm$ 4 at 25°C $\pm$ 4 at 25°C $\pm$ 1 $\pm$ 0. $\pm$ 1 $\pm$ 0. $\pm$ 2 $\pm$ 2 $\pm$ 2 $\pm$ 2 $\pm$ 2 $\pm$ 3 $\pm$ 4 $\pm$ 6 $\pm$ 4 in $\pm$ 2 $\pm$ 6 $\pm$ 7 $\pm$ 6 $\pm$ 7 $\pm$ 9 $\pm$	minutes. on of rosin in w 120±5 see  at the  OpF kHz /rms  10µF 120±2 0.5±0.  DC voltage	veight conds  < C 24Hz IVrms ge not

			1	#AEC-Q200					
No	AEC-Q200	0 Test Item	Temperature Compensating Type	cifications.  High Dielectric Type	AEC-Q200 Test Method				
17	Board Flex	Appearance	No marking defects		Solder the capacitor on the test jig (glass epoxy board) shown in Fig1 using a eutectic solder. Then apply a force in the direction shown in Fig 2 for 5±1sec. The soldering should be done by the reflow method and should be conducted with care so that the				
		Capacitance	Within ±5.0% or ±0.5pF	Within specified tolerance	soldering is uniform and free of defects such as heat shock.				
		Change Q/D.F.	(Whichever is larger) 30pFmin. : Q≧1000	R7: 0.125max	Type a b c GRT03 0.3 0.9 0.3				
			30pFmax.: Q ≧400+20C		GRT15 0.5 1.5 0.6 GRT18 0.6 2.2 0.9				
			C: Nominal Capacitance(pF)		GRT21 0.8 3.0 1.3				
		Insulation Resistance	More than 10,000MΩ or 500Ω·F	R7: More than $1000M\Omega$ or $50\Omega \cdot F$ (Whichever is smaller)	GRT31 2.0 4.4 1.7 GRT32 2.0 4.4 2.6				
			(William (GRT03,15:0.8mm)		Pressurizing speed:1.0mm/sec Pressurize  Capacitance meter 45 45 (Chip thickness > 0.85mm High Dielectric Type) Fig.2 Flexure: ≦2 (Temperature Compensating	rank			
18	Terminal Strength	Appearance	No marking defects		Solder the capacitor to the test jig (glass epoxy board) shown in Fig.3 using a eutectic solder. Then apply *18N force in parallel with	th			
	Ortengui	Capacitance	Within specified tolerance		the test jig for 60sec.				
		Change Q/D.F.	30pFmin. : Q≧1000	R7: 0.125max	The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is				
			30pFmax.: Q ≧400+20C C: Nominal Capacitance(pF)		uniform and gree of defects such as heat shock				
40	Beam Load Tes	Insulation Resistance	More than 10,000MΩ or 500Ω •F (Whichever is smaller)	(Whichever is smaller)	GRT03				
19	Beam Load Tes	t	< Chip L dimension : 2.5mm max.  Chip thickness	> s > 0.5mm rank : 20N	Place the capacitor in the beam load fixture as Fig 4. Apply a force.				
			Chip thickness = 0.5mm rank : 8N  Chip thickness = 0.3mm rank : 5N  Chip thickness < 0.3mm rank : 2.5N  < Chip L dimension : 3.2mm min. >  Chip thickness < 1.25mm rank : 15N  Chip thickness ≥ 1.25mm rank : 54.5N		< Chip Length : 2.5mm max. >  Iron Board  < Chip Length : 3.2mm min. >				
					Fig.4  Speed supplied the Stress Load : 0.5mm / sec.				

			Specific	ations.	
No	AEC-Q2	00 Test Item	Temperature Compensating Type	High Dielectric Type	AEC-Q200 Test Method
21	Capacitance	Capacitance	Within the specified tolerance.	R7 : Within ±15%	The capacitance change should be measured after 5 min. at
	Temperature	Change	(Table A)	(-55°C to +125°C)	each specified temperature stage.
	Characteristics				(1)Temperature Compensating Type
					The temperature coefficient is determind using the capacitance
					measured in step 3 as a reference. When cycling the temperature
					sequentially from step1 through 5 (Δ C: +25°C to +125°C) the
					capacitance should be within the specified tolerance for the
					temperature coefficient and capacitance change as Table A-1. The
					capacitance drift is caluculated by dividing the differences
					betweeen the maximum and minimum measured values in the step
		Temperature	Within the specified tolerance.		1,3 and 5 by the cap value in step 3.
		'	(Table A)		Step Temperature.(°C)
		Coemicent	(Table A)		1 25±2
					2 -55±3
					3 25±2
					4 125±3(for Δ C/R7)
		Capacitance	Within ±0.2% or ±0.05 pF	7	5 25±2
		Drift	(Whichever is larger.)		
					(2) High Dielectric Constant Type
					The ranges of capacitance change compared with the above 25°C
					value over the temperature ranges shown in the table should be
					within the specified ranges.
				/	Initial measurement for high dielectric constant type.
				/	Perform a heat treatment at 150+0/-10°C for one hour
				/	and then set for 24±2 hours at room temperature.
				V	Perform the initial measurement.

#### Table A

	Tubic / t									
Ī		Naminal Values	Capacitance Change from 25°C (%)							
	Char.	Nominal Values (ppm/°C)	-5	-55 -30 -10		-30		0		
		(ppiii/ C)	Max.	Min.	Max.	Min.	Max.	Min.		
	5C	0± 30	0.58	-0.24	0.40	-0.17	0.25	-0.11		

Note 1: Nominal values denote the temperature coefficient within a range of 25°C to 125°C(for △C).

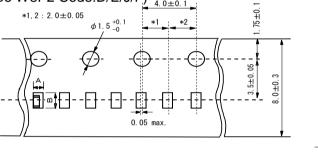
## 1.Tape Carrier Packaging(Packaging Code:D/E/W/F/L/J/K)

1.1 Minimum Quantity(pcs./reel)

			φ180mm reel		φ330mr	n reel
	Type	Paper	Таре	Plastic Tape	Paper Tape	Plastic Tape
		Code:D/E	Code:W	Code:L	Code:J/F	Code:K
GRT03		15000(W8P2)	30000(W8P1)		50000(W8P2)	
GRT15	5(LWTDimensions Tolerance:±0.05)	10000(W8P2)	20000(W8P1)		50000(W8P2)	
OKTIS	5(LWTDimensions Tolerance:±0.1min.)	10000(W8P2)			40000(W8P2)	
GRT18		4000			10000	
	6	4000			10000	
GRT21	9	4000			10000	
	В			3000		10000
	6	4000			10000	
GRT31	9	4000			10000	
GRISI	М			3000		10000
	С			2000		6000
CDT22	N			2000		8000
GRT32	D/E			1000		4000

## 1.2 Dimensions of Tape

(1)GRT03/15(Paper Tape W8P2 Code:D/E/J/F)

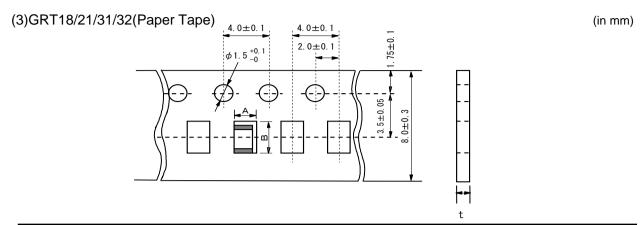


Type	_	Dimensions Tolerance(Chip)			A *3	B *3	4	
Туре	₽	L	W	Т	АЗ	БЭ	ι	
GRT03	3	0.6±0.03	0.3±0.03	0.3±0.03	0.37	0.67	0.5 max.	
GKT03	٥	0.6±0.05	0.3±0.05	0.3±0.05	0.39	0.69	U.S IIIax.	
		1.0±0.05	0.5±0.05	0.5±0.05	0.65	1.15		
GRT15	5	1.0±0.1	0.5±0.1	0.5±0.1	0.70	1.20	0.8 max.	
		1.0±0.2	0.5±0.2	0.5±0.2	0.75	1.20		

(2)GRT03/15Paper Tape W8P1 Code:W)  $\phi_{1.0\pm0.05}$   $\phi_{1.5}$   $\phi_{1.0\pm0.05}$ \*3 Nominal value

Type	_	Dimensions Tolerance(Chip)			A *3	B *3	+	
Туре		L	W	Т	A 3	ьз	l l	
GRT03	2	0.6±0.03	0.3±0.03	0.3±0.03	0.37	0.67	0.5 max.	
GKT03	K103 3	0.6±0.05	0.3±0.05	0.3±0.05	0.39	0.69	U.S IIIax.	
GRT15	5	1.0±0.05	0.5±0.05	0.5±0.05	0.65	1.15	0.8 max.	

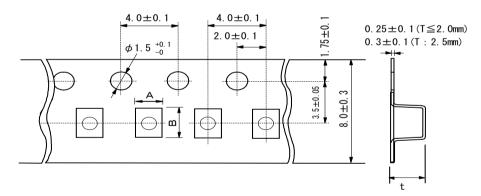
<sup>\*3</sup> Nominal value



Туре		Dimen	sions Tolerance	e(Chip)	Α	В	+
Туре	,	L	W	Т	Α	ם	
		1.6±0.1	0.8±0.1	0.8±0.1	1.05±0.10	1.85±0.10	
GRT18	8	1.6±0.15	0.8±0.15	0.8±0.15	1.00±0.10	1.00±0.10	
		1.6±0.2	0.8±0.2	0.8±0.2	1.10±0.10	2.00±0.10	
	6			0.6±0.1			
	U	2.0±0.1	1.25±0.1	0.6+0/-0.15		2.30±0.15	
GRT21		2.0±0.1	.1 1.25±0.1	0.85±0.1	1.55±0.15		1.1 max.
	9			0.85+0/-0.2			
		2.0±0.15	1.25±0.15	0.85±0.1			
GRT31	6	3.2±0.15	1.6±0.15	0.6±0.1			
	9	J.2±0.15	1.0±0.15	0.85±0.1 2.00±0.20	2.00±0.20	3.60±0.20	
	9	3.2±0.2	1.6±0.2	0.05±0.1			

## (4)GRT21/31/32(Plastic Tape)

(in mm)



Type		Dimen	sions Tolerance	e(Chip)	Α	В	4	
Туре	,	L	W	Т	A	Б	ι	
		2.0±0.1	1.25±0.1	1.25±0.1	1.45±0.20	2.25±0.20	1.7 max.	
GRT21	В	2.0±0.15	1.25±0.15	1.25±0.15	1.50±0.20	2.30±0.20	2.0 max.	
			2.0±0.2	1.25±0.2	1.25±0.2	1.50±0.20	2.30±0.20	2.0 IIIax.
	М	3.2±0.15	1.6±0.15	1.15±0.1			1.7 max.	
GRT31	IVI	3.2±0.2	1.6±0.2	1.15±0.15	1.90±0.20	3.50±0.20	1.7 IIIax.	
	С	3.2±0.2	1.0±0.2	1.6±0.2			2.5 max.	
	Ν			1.35±0.15		0±0.20 3.50±0.20	2.5 max.	
GRT32	D	3.2±0.3	2.5±0.2	2.0±0.2	2.80±0.20		3.0 max.	
	Е			2.5±0.2			3.7 max.	

Fig.1 Package Chips

(in mm)

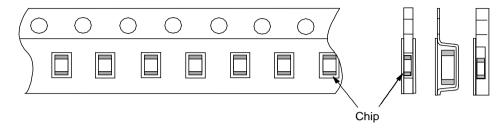


Fig.2 Dimensions of Reel

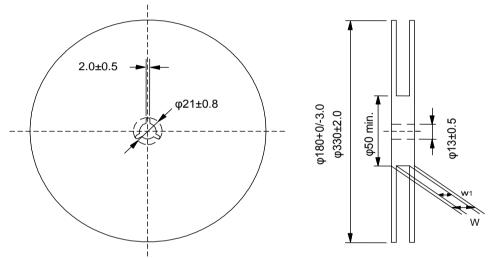
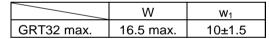
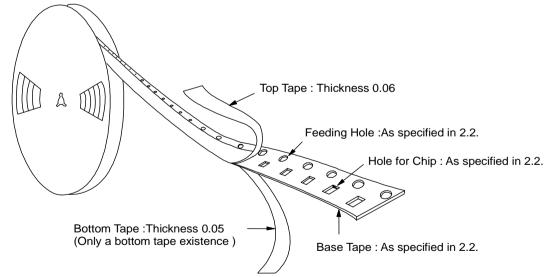
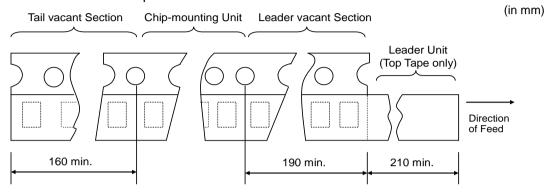


Fig.3 Taping Diagram



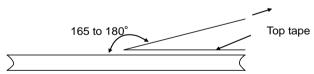


- 1.3 Tapes for capacitors are wound clockwise shown in Fig.3. (The sprocket holes are to the right as the tape is pulled toward the user.)
- 1.4 Part of the leader and part of the vacant section are attached as follows.



- 1.5 Accumulate pitch: 10 of sprocket holes pitch = 40±0.3mm
- 1.6 Chip in the tape is enclosed by top tape and bottom tape as shown in Fig.1.
- 1.7 The top tape and base tape are not attached at the end of the tape for a minimum of 5 pitches.
- 1.8 There are no jointing for top tape and bottom tape.
- 1.9 There are no fuzz in the cavity.
- 1.10 Break down force of top tape : 5N min.

  Break down force of bottom tape : 5N min. (Only a bottom tape existence)
- 1.11 Reel is made by resin and appeaser and dimension is shown in Fig 1. There are possibly to change the material and dimension due to some impairment.
- 1.12 Peeling off force: 0.1N to 0.6N\* in the direction as shown below.
  - \* GRT03:0.05N to 0.5N



1.13 Label that show the customer parts number, our parts number, our company name, inspection number and quantity, will be put in outside of reel.

## ■Limitation of Applications

Please contact us before using our products for the applications listed below which require especially high reliability for the prevention of defects which might directly cause damage to the third party's life, body or property.

- ①Aircraft equipment ②Aerospace equipment ③Undersea equipment ④Power plant control equipment
- ⑤Medical equipment ⑥Transportation equipment(vehicles,trains,ships,etc.) ⑦Traffic signal equipment
- (1) Application of similar complexity and/or reliability requirements to the applications listed in the above.

This series is designed for use in Car Multimedia, Car Interior, Car Comfort application and General Electronic equipment. It shall not be used in applications critical to passenger safety and car driving function(e.g. ABS,AIRBAG, etc.).

## ■ Storage and Operation condition

- 1. The performance of chip monolithic ceramic capacitors may be affected by the storage conditions.
- 1-1. Store the capacitors in the following conditions:

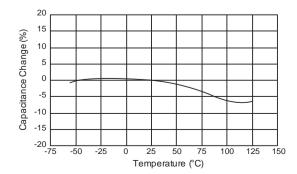
  Room Temperature of +5°C to +40°C and a Relative Humidity of 20% to 70%.
  - (1) Sunlight, dust, rapid temperature changes, corrosive gas atmosphere, or high temperature and humidity conditions during storage may affect solderability and packaging performance. Therefore, please maintain the storage temperature and humidity. Use the product within six months, as prolonged storage may cause oxidation of the terminations (outer electrodes).
  - (2) Please confirm solderability before using after six months. Store the capacitors without opening the original bag. Even if the storage period is short, do not exceed the specified atmospheric conditions.
- 1-2. Corrosive gas can react with the termination (external) electrodes or lead wires of capacitors, and result in poor solderability. Do not store the capacitors in an atmosphere consisting of corrosive gas (e.g.,hydrogen sulfide, sulfur dioxide, chlorine, ammonia gas etc.).
- 1-3. Due to moisture condensation caused by rapid humidity changes, or the photochemical change caused by direct sunlight on the terminal electrodes and/or the resin/epoxy coatings, the solderability and electrical performance may deteriorate. Do not store capacitors under direct sunlight or in high huimidity conditions

## ■ Rating

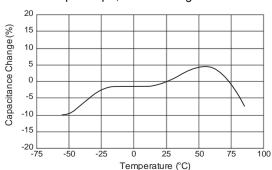
#### 1.Temperature Dependent Characteristics

- 1. The electrical characteristics of the capacitor can change with temperature.
- 1-1. For capacitors having larger temperature dependency, the capacitance may change with temperature changes. The following actions are recommended in order to ensure suitable capacitance values.
  - (1) Select a suitable capacitance for the operating temperature range.
  - (2) The capacitance may change within the rated temperature. When you use a high dielectric constant type capacitor in a circuit that needs a tight (narrow) capacitance tolerance (e.g., a time-constant circuit), please carefully consider the temperature characteristics, and carefully confirm the various characteristics in actual use conditions and the actual system.

[Example of Temperature Caracteristics X7R(R7)] Sample:  $0.1\mu F$ , Rated Voltage 50VDC



[Example of Temperature Characteristics X5R(R6)] Sample: 22µF, Rated Voltage 4VDC



## 2.Measurement of Capacitance

- 1. Measure capacitance with the voltage and frequency specified in the product specifications.
- 1-1. The output voltage of the measuring equipment may decrease occasionally when capacitance is high. Please confirm whether a prescribed measured voltage is impressed to the capacitor.
- 1-2. The capacitance values of high dielectric constant type capacitors change depending on the AC voltage applied. Please consider the AC voltage characteristics when selecting a capacitor to be used in a AC circuit.

### 3.Applied Voltage

- 1. Do not apply a voltage to the capacitor that exceeds the rated voltage as called out in the specifications.
- 1-1. Applied voltage between the terminals of a capacitor shall be less than or equal to the rated voltage.
  - (1) When AC voltage is superimposed on DC voltage, the zero-to-peak voltage shall not exceed the rated DC voltage. When AC voltage or pulse voltage is applied, the peak-to-peak voltage shall not exceed the rated DC voltage.
  - (2) Abnormal voltages (surge voltage, static electricity, pulse voltage, etc.) shall not exceed the rated DC voltage.



(E : Maximum possible applied voltage.)

1-2. Influence of over voltage

Over voltage that is applied to the capacitor may result in an electrical short circuit caused by the breakdown of the internal dielectric layers.

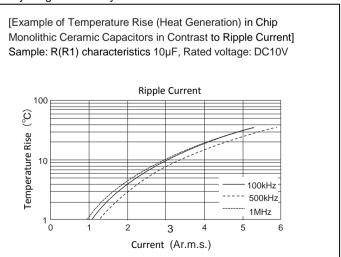
The time duration until breakdown depends on the applied voltage and the ambient temperature.

#### 4. Type of Applied Voltage and Self-heating Temperature

- 1. Confirm the operating conditions to make sure that no large current is flowing into the capacitor due to the continuous application of an AC voltage or pulse voltage.
  - When a DC rated voltage product is used in an AC voltage circuit or a pulse voltage circuit, the AC current or pulse current will flow into the capacitor; therefore check the self-heating condition.
  - Please confirm the surface temperature of the capacitor so that the temperature remains within the upper limits of the operating temperature, including the rise in temperature due to self-heating. When the capacitor is used with a high-frequency voltage or pulse voltage, heat may be generated by dielectric loss.

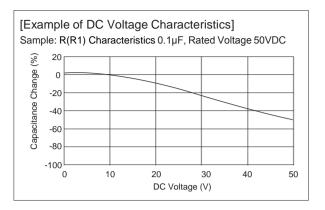
<Applicable to Rated Voltage of less than 100VDC>

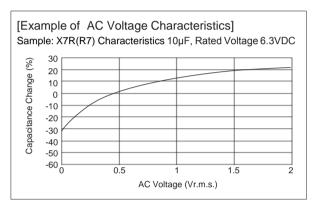
1-1. The load should be contained to the level such that when measuring at atmospheric temperature of 25°C, the product's self-heating remains below 20°C and the surface temperature of the capacitor in the actual circuit remains within the maximum operating temperature.



## 5. DC Voltage and AC Voltage Characteristic

- The capacitance value of a high dielectric constant type capacitor changes depending on the DC voltage applied. Please consider the DC voltage characteristics when a capacitor is selected for use in a DC circuit.
- 1-1. The capacitance of ceramic capacitors may change sharply depending on the applied voltage. (See figure) Please confirm the following in order to secure the capacitance.
- (1) Determine whether the capacitance change caused by the applied voltage is within the allowed range.
- (2) In the DC voltage characteristics, the rate of capacitance change becomes larger as voltage increases, even if the applied voltage is below the rated voltage. When a high dielectric constant type capacitor is used in a circuit that requires a tight (narrow) capacitance tolerance (e.g., a time constant circuit), please carefully consider the voltage characteristics, and confirm the various characteristics in the actual operating conditions of the system.
- The capacitance values of high dielectric constant type capacitors changes depending on the AC voltage applied.
   Please consider the AC voltage characteristics when selecting a capacitor to be used in a AC circuit.

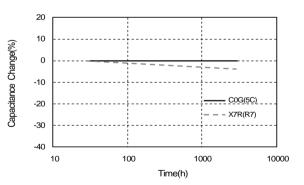




## 6. Capacitance Aging

1. The high dielectric constant type capacitors have an Aging characteristic in which the capacitance value decreases with the passage of time. When you use a high dielectric constant type capacitors in a circuit that needs a tight (narrow) capacitance tolerance (e.g., a time-constant circuit), please carefully consider the characteristics of these capacitors, such as their aging, voltage, and temperature characteristics. In addition, check capacitors using your actual appliances at the intended environment and operating conditions.

## [ Example of Change Over Time (Aging characteristics) ]

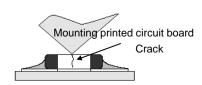


## 7.Vibration and Shock

- 1. Please confirm the kind of vibration and/or shock, its condition, and any generation of resonance.

  Please mount the capacitor so as not to generate resonance, and do not allow any impact on the terminals.
- Mechanical shock due to being dropped may cause damage or a crack in the dielectric material of the capacitor.Do not use a dropped capacitor because the quality and reliability may be deteriorated.
- 3. When printed circuit boards are piled up or handled, the corner of another printed circuit board should not be allowed to hit the capacitor in order to avoid a crack or other damage to the capacitor.

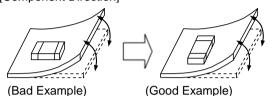




## ■Soldering and Mounting

#### 1.Mounting Position

- 1. Confirm the best mounting position and direction that minimizes the stress imposed on the capacitor during flexing or bending the printed circuit board.
- 1-1. Choose a mounting position that minimizes the stress imposed on the chip during flexing or bending of the board. [Component Direction]



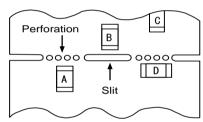
Locate chip horizontal to the direction in which stress acts.

## [Chip Mounting Close to Board Separation Point]

It is effective to implement the following measures, to reduce stress in separating the board.

It is best to implement all of the following three measures; however, implement as many measures as possible to reduce stress.

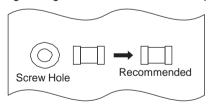
Contents of Measures	Stress Level
(1) Turn the mounting direction of the component parallel to the board separation surface.	A > D*1
(2) Add slits in the board separation part.	A > B
(3) Keep the mounting position of the component away from the board separation surface.	A > C



\*1 A > D is valid when stress is added vertically to the perforation as with Hand Separation. If a Cutting Disc is used, stress will be diagonal to the PCB, therefore A > D is invalid.

## [Mounting Capacitors Near Screw Holes]

When a capacitor is mounted near a screw hole, it may be affected by the board deflection that occurs during the tightening of the screw. Mount the capacitor in a position as far away from the screw holes as possible.



### 2.Information before Mounting

- 1. Do not re-use capacitors that were removed from the equipment.
- 2. Confirm capacitance characteristics under actual applied voltage.
- 3. Confirm the mechanical stress under actual process and equipment use.
- 4. Confirm the rated capacitance, rated voltage and other electrical characteristics before assembly.
- 5. Prior to use, confirm the solderability of capacitors that were in long-term storage.
- 6. Prior to measuring capacitance, carry out a heat treatment for capacitors that were in long-term storage.
- 7.The use of Sn-Zn based solder will deteriorate the reliability of the MLCC.

  Please contact our sales representative or product engineers on the use of Sn-Zn based solder in advance.

## 3. Maintenance of the Mounting (pick and place) Machine

- 1. Make sure that the following excessive forces are not applied to the capacitors.
- 1-1. In mounting the capacitors on the printed circuit board, any bending force against them shall be kept to a minimum to prevent them from any damage or cracking. Please take into account the following precautions and recommendations for use in your process.
  - (1) Adjust the lowest position of the pickup nozzle so as not to bend the printed circuit board.
  - (2) Adjust the nozzle pressure within a static load of 1N to 3N during mounting.

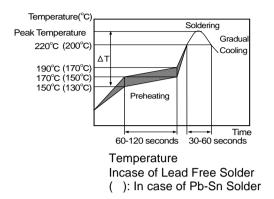


2. Dirt particles and dust accumulated between the suction nozzle and the cylinder inner wall prevent the nozzle from moving smoothly. This imposes greater force upon the chip during mounting, causing cracked chips. Also, the locating claw, when worn out, imposes uneven forces on the chip when positioning, causing cracked chips. The suction nozzle and the locating claw must be maintained, checked and replaced periodically.

## 4-1.Reflow Soldering

- When sudden heat is applied to the components, the mechanical strength of the components will decrease because a sudden temperature change causes deformation inside the components. In order to prevent mechanical damage to the components, preheating is required for both the components and the PCB.
   Preheating conditions are shown in table 1. It is required to keep the temperature differential between the solder and the components surface (ΔT) as small as possible.
- Solderability of tin plating termination chips might be deteriorated when a low temperature soldering profile where the peak solder temperature is below the melting point of tin is used. Please confirm the solderability of tin plated termination chips before use.
- When components are immersed in solvent after mounting, be sure to maintain the temperature difference (ΔT) between the component and the solvent within the range shown in the table 1.

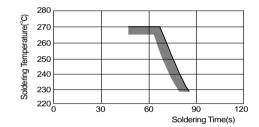
[Standard Conditions for Reflow Soldering]



[Allowable Reflow Soldering Temperature and Time]

Table 1

 <del>4010 1</del>				
Series	Chip Dimension(L/W) Code	Temperature Differential		
GRT	03/15/18/21/31	ΔT≦190°C		
GRT	32	ΔT≦130°C		



In the case of repeated soldering, the accumulated soldering time must be within the range shown above.

Recommended Conditions

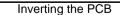
	Pb-Sn Solder	Lead Free Solder
Peak Temperature	230 to 250°C	240 to 260°C
Atmosphere	Air	Air or N <sub>2</sub>

Pb-Sn Solder: Sn-37Pb

Lead Free Solder: Sn-3.0Ag-0.5Cu

- 4. Optimum Solder Amount for Reflow Soldering
- 4-1. Overly thick application of solder paste results in a excessive solder fillet height.

  This makes the chip more susceptible to mechanical and thermal stress on the board and may cause the chips to crack.
- 4-2. Too little solder paste results in a lack of adhesive strength on the termination, which may result in chips breaking loose from the PCB.
- 4-3. Please confirm that solder has been applied smoothly to the termination.



Make sure not to impose any abnormal mechanical shocks to the PCB.

## 4-2.Flow Soldering

1. Do not apply flow soldering to chips not listed in Table 2.

#### Table 2

Series	Chip Dimension (L/W) Code	Temperature Differential
GRT	18/21/31	ΔΤ≦150°C

- 2. When sudden heat is applied to the components, the mechanical strength of the components will decrease because a sudden temperature change causes deformation inside the components. In order to prevent mechanical damage to the components, preheating is required for both of the components and the PCB. Preheating conditions are shown in table 2. It is required to keep the temperature differential between the solder and the components surface (ΔT) as low as possible.
- 3. Excessively long soldering time or high soldering temperature can result in leaching of the terminations, causing poor adhesion or a reduction in capacitance value due to loss of contact between the inner electrodes and terminations.
- 4. When components are immersed in solvent after mounting, be sure to maintain the temperature differential (ΔT) between the component and solvent within the range shown in the table 2.

## **Recommended Conditions**

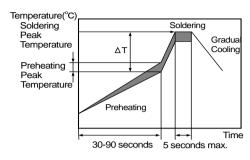
	Pb-Sn Solder	Lead Free Solder
Preheating Peak Temperature	90 to 110°C	100 to 120°C
Soldering Peak Temperature	240 to 250°C	250 to 260°C
Atmosphere	Air	Air or N2

Pb-Sn Solder: Sn-37Pb

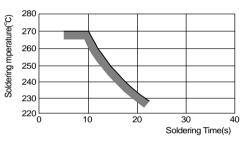
Lead Free Solder: Sn-3.0Ag-0.5Cu

- 5. Optimum Solder Amount for Flow Soldering
- 5-1. The top of the solder fillet should be lower than the thickness of the components. If the solder amount is excessive, the risk of cracking is higher during board bending or any other stressful condition.

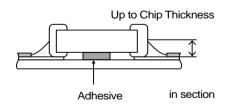
## [Standard Conditions for Flow Soldering]



## [Allowable Flow Soldering Temperature and Time]



In the case of repeated soldering, the accumulated soldering time must be within the range shown above.



#### 4-3. Correction of Soldered Portion

When sudden heat is applied to the capacitor, distortion caused by the large temperature difference occurs internally, and can be the cause of cracks. Capacitors also tend to be affected by mechanical and thermal stress depending on the board preheating temperature or the soldering fillet shape, and can be the cause of cracks. Please refer to "1. PCB Design" or "3. Optimum solder amount" for the solder amount and the fillet shapes.

- 1. Correction with a Soldering Iron
  - 1-1. In order to reduce damage to the capacitor, be sure to preheat the capacitor and the mounting board.

    Preheat to the temperature range shown in Table 3. A hot plate, hot air type preheater, etc. can be used for preheating.
- 1-2. After soldering, do not allow the component/PCB to cool down rapidly.
- 1-3. Perform the corrections with a soldering iron as quickly as possible. If the soldering iron is applied too long, there is a possibility of causing solder leaching on the terminal electrodes, which will cause deterioration of the adhesive strength and other problems.

Table 3

Series	Chip Dimension (L/W) Code	Temperature of Soldering Iron tip	Preheating Temperature	Temperature Differential(ΔT)	Atmosphere
GRT	03/15/18/21/31	350°C max.	150°C min.	ΔΤ≦190°C	Air
GRT	32	280°C max.	150°C min.	ΔΤ≦130°C	Air

<sup>\*</sup>Applicable for both Pb-Sn and Lead Free Sold Pb-Sn Solder: Sn-37Pb

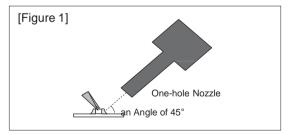
Lead Free Solder: Sn-3.0Ag-0.5Cu

- 2. Correction with Spot Heater
  - Compared to local heating with a soldering iron, hot air heating by a spot heater heats the overall component and board, therefore, it tends to lessen the thermal shock. In the case of a high density mounted board, a spot heater can also prevent concerns of the soldering iron making direct contact with the component.
- 2-1. If the distance from the hot air outlet of the spot heater to the component is too close, cracks may occur due to thermal shock. To prevent this problem, follow the conditions shown in Table 4.
- 2-2. In order to create an appropriate solder fillet shape, it is recommended that hot air be applied at the angle shown in Figure 1.

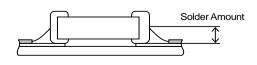
Table 4

Table +	
Distance	5mm or more
Hot Air Application angle	45° *Figure 1
Hot Air Temperature Nozzle Outlet	400°C max.
	Less than 10 seconds
Application Time	(3216M / 1206 size or smaller)
	Less than 30 seconds
	(3225M / 1210 size or larger)

(3216M, 3225M: Metric size code)



- 3. Optimum solder amount when re-working with a soldering iron
- 3-1. If the solder amount is excessive, the risk of cracking is higher during board bending or any other stressful condition. Too little solder amount results in a lack of adhesive strength on the outer electrode termination, which may result in chips breaking loose from the PCB.
  Please confirm that solder has been applied smoothly is
- and rising to the end surface of the chip.
  3-2. A soldering iron with a tip of ø3mm or smaller should be used.
  It is also necessary to keep the soldering iron from touching the components during the re-work.
- 3-3. Solder wire with Ø0.5mm or smaller is required for soldering.



in section

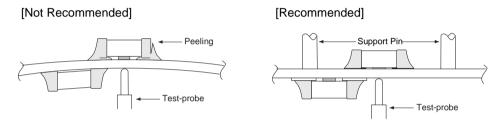
<sup>\*</sup> Please manage  $\Delta$  T in the temperature of soldering iron and the preheating temperature.

## 5.Washing

Excessive ultrasonic oscillation during cleaning can cause the PCBs to resonate, resulting in cracked chips or broken solder joints. Take note not to vibrate PCBs.

## **6.Electrical Test on Printed Circuit Board**

- 1. Confirm position of the support pin or specific jig, when inspecting the electrical performance of a capacitor after mounting on the printed circuit board.
  - 1-1. Avoid bending the printed circuit board by the pressure of a test-probe, etc. The thrusting force of the test probe can flex the PCB, resulting in cracked chips or open solder joints. Provide support pins on the back side of the PCB to prevent warping or flexing. Install support pins as close to the test-probe as possible.
  - 1-2. Avoid vibration of the board by shock when a test -probe contacts a printed circuit board.



#### 7. Printed Circuit Board Cropping

- 1. After mounting a capacitor on a printed circuit board, do not apply any stress to the capacitor that caused bending or twisting the board.
  - 1-1. In cropping the board, the stress as shown may cause the capacitor to crack. Cracked capacitors may cause deterioration of the insulation resistance, and result in a short. Avoid this type of stress to a capacitor.



- 2. Check the cropping method for the printed circuit board in advance.
  - 2-1. Printed circuit board cropping shall be carried out by using a jig or an apparatus (Disc separator, router type separator, etc.) to prevent the mechanical stress that can occur to the board.

Board Separation Method	Hand Separation	(1) Board Separation Jig	Board Separa	tion Apparatus
Board Separation Method	Nipper Separation	(1) Board Separation sig	Disc Separator	3) Router Type Separator
Level of stress on board	High	Medium	Medium	Low
Recommended	×	Δ*	Δ*	$\bigcirc$
Notes	Hand and nipper separation apply a high level of stress. Use another method.	Board handling     Board bending direction     Layout of capacitors	Board handling     Layout of slits     Design of V groove     Arrangement of blades     Controlling blade life	Board handling

<sup>\*</sup> When a board separation jig or disc separator is used, if the following precautions are not observed, a large board deflection stress will occur and the capacitors may crack.

Use router type separator if at all possible.

## (1) Example of a suitable jig

[Outline of jig]

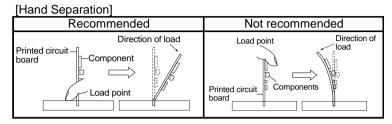
[In the case of Single-side Mounting]

An outline of the board separation jig is shown as follows.

Recommended example: Stress on the component mounting position can be minimized by holding the portion close to the jig, and bend in the direction towards the side where the capacitors are mounted. Not recommended example: The risk of cracks occurring in the capacitors increases due to large stress being applied to the component mounting position, if the portion away from the jig is held and bent in the direction opposite the side where the capacitors are mounted.

Printed Circuit Board V-groove

Board Cropping Jig



[In the case of Double-sided Mounting]

Since components are mounted on both sides of the board, the risk of cracks occurring can not be avoided with the above method. Therefore, implement the following measures to prevent stress from being applied to the components. (Measures)

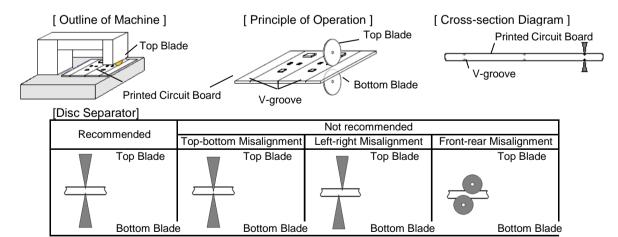
- (1) Consider introducing a router type separator.
  - If it is difficult to introduce a router type separator, implement the following measures. (Refer to item 1. Mounting Position)
- (2) Mount the components parallel to the board separation surface.
- (3) When mounting components near the board separation point, add slits in the separation position near the component.
- (4) Keep the mounting position of the components away from the board separation point.

#### (2) Example of a Disc Separator

An outline of a disc separator is shown as follows. As shown in the Principle of Operation, the top blade and bottom blade are aligned with the V-grooves on the printed circuit board to separate the board. In the following case, board deflection stress will be applied and cause cracks in the capacitors.

- (1) When the adjustment of the top and bottom blades are misaligned, such as deviating in the top-bottom, left-right or front-rear directions
- (2) The angle of the V groove is too low, depth of the V groove is too shallow, or the V groove is misaligned top-bottom

IF V groove is too deep, it is possible to brake when you handle and carry it. Carefully design depth of the V groove with consideration about strength of material of the printed circuit board.



[V-groove Design] Example of	Not Recommended						
Recommended	Left-right Misalignment	Low-Angle	Depth too Shallow	Depth too Deep			

## **↑**Caution

## (3) Example of Router Type Separator

The router type separator performs cutting by a router rotating at a high speed. Since the board does not bend in the cutting process, stress on the board can be suppressed during board separation.

When attaching or removing boards to/from the router type separator, carefully handle the boards to prevent bending.



#### 8. Assembly

#### 1. Handling

If a board mounted with capacitors is held with one hand, the board may bend.

Firmly hold the edges of the board with both hands when handling.

If a board mounted with capacitors is dropped, cracks may occur in the capacitors.

Do not use dropped boards, as there is a possibility that the quality of the capacitors may be impaired.

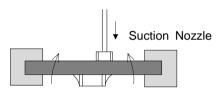
#### 2. Attachment of Other Components

#### 2-1. Mounting of Other Components

Pay attention to the following items, when mounting other components on the back side of the board after capacitors have been mounted on the opposite side.

When the bottom dead point of the suction nozzle is set too low, board deflection stress may be applied to the capacitors on the back side (bottom side), and cracks may occur in the capacitors.

- · After the board is straightened, set the bottom dead point of the nozzle on the upper surface of the board.
- · Periodically check and adjust the bottom dead point.



#### 2-2. Inserting Components with Leads into Boards

When inserting components (transformers, IC, etc.) into boards, bending the board may cause cracks in the capacitors or cracks in the solder. Pay attention to the following.

- · Increase the size of the holes to insert the leads, to reduce the stress on the board during insertion.
- · Fix the board with support pins or a dedicated jig before insertion.
- Support below the board so that the board does not bend. When using multiple support pins on the board, periodically confirm that there is no difference in the height of each support pin.



## 2-3. Attaching/Removing Sockets

When the board itself is a connector, the board may bend when a socket is attached or removed. Plan the work so that the board does not bend when a socket is attached or removed.



## 2-4. Tightening Screws

The board may be bent, when tightening screws, etc. during the attachment of the board to a shield or chassis. Pay attention to the following items before performing the work.

- · Plan the work to prevent the board from bending.
- · Use a torque screwdriver, to prevent over-tightening of the screws.
- The board may bend after mounting by reflow soldering, etc. Please note, as stress may be applied to the chips by forcibly flattening the board when tightening the screws.



#### Others

#### 1. Under Operation of Equipment

- 1-1. Do not touch a capacitor directly with bare hands during operation in order to avoid the danger of an electric shock.
- 1-2. Do not allow the terminals of a capacitor to come in contact with any conductive objects (short-circuit). Do not expose a capacitor to a conductive liquid, inducing any acid or alkali solutions.
- 1-3. Confirm the environment in which the equipment will operate is under the specified conditions.
  - Do not use the equipment under the following environments.
  - (1) Being spattered with water or oil.
  - (2) Being exposed to direct sunlight.
  - (3) Being exposed to ozone, ultraviolet rays, or radiation.
  - (4) Being exposed to toxic gas (e.g., hydrogen sulfide, sulfur dioxide, chlorine, ammonia gas etc.)
  - (5) Any vibrations or mechanical shocks exceeding the specified limits.
  - (6) Moisture condensing environments.
- 1-4. Use damp proof countermeasures if using under any conditions that can cause condensation.

#### 2. Others

#### 2-1. In an Emergency

- (1) If the equipment should generate smoke, fire, or smell, immediately turn off or unplug the equipment.

  If the equipment is not turned off or unplugged, the hazards may be worsened by supplying continuous power.
- (2) In this type of situation, do not allow face and hands to come in contact with the capacitor or burns may be caused by the capacitor's high temperature.

#### 2-2. Disposal of waste

When capacitors are disposed of, they must be burned or buried by an industrial waste vendor with the appropriate licenses.

#### 2-3. Circuit Design

(1) Addition of Fail Safe Function

Capacitors that are cracked by dropping or bending of the board may cause deterioration of the insulation resistance, and result in a short. If the circuit being used may cause an electrical shock, smoke or fire when a capacitor is shorted, be sure to install fail-safe functions, such as a fuse, to prevent secondary accidents.

(2) This series are not safety standard certified products.

## 2-4. Remarks

Failure to follow the cautions may result, worst case, in a short circuit and smoking when the product is used. The above notices are for standard applications and conditions. Contact us when the products are used in special mounting conditions.

Select optimum conditions for operation as they determine the reliability of the product after assembly.

The data herein are given in typical values, not guaranteed ratings.

## Rating

#### 1.Operating Temperature

- 1. The operating temperature limit depends on the capacitor.
- 1-1. Do not apply temperatures exceeding the maximum operating temperature.

  It is necessary to select a capacitor with a suitable rated temperature that will cover the operating temperature range.

  It is also necessary to consider the temperature distribution in equipment and the seasonal temperature variable factor.
- 1-2. Consider the self-heating factor of the capacitor

  The surface temperature of the capacitor shall not exceed the maximum operating temperature including self-heating.

## 2.Atmosphere Surroundings (gaseous and liquid)

- 1. Restriction on the operating environment of capacitors.
- 1-1. Capacitors, when used in the above, unsuitable, operating environments may deteriorate due to the corrosion of the terminations and the penetration of moisture into the capacitor.
- 1-2. The same phenomenon as the above may occur when the electrodes or terminals of the capacitor are subject to moisture condensation.
- 1-3. The deterioration of characteristics and insulation resistance due to the oxidization or corrosion of terminal electrodes may result in breakdown when the capacitor is exposed to corrosive or volatile gases or solvents for long periods of time.

## 3.Piezo-electric Phenomenon

 When using high dielectric constant type capacitors in AC or pulse circuits, the capacitor itself vibrates at specific frequencies and noise may be generated.
 Moreover, when the mechanical vibration or shock is added to capacitor, noise may occur.

## ■ Soldering and Mounting

#### 1.PCB Design

- 1. Notice for Pattern Forms
- 1-1. Unlike leaded components, chip components are susceptible to flexing stresses since they are mounted directly on the substrate.
  - They are also more sensitive to mechanical and thermal stresses than leaded components.
  - Excess solder fillet height can multiply these stresses and cause chip cracking.
  - When designing substrates, take land patterns and dimensions into consideration to eliminate the possibility of excess solder fillet height.
- 1-2. There is a possibility of chip cracking caused by PCB expansion/contraction with heat, because stress on a chip is different depending on PCB material and structure. When the thermal expansion coefficient greatly differs between the board used for mounting and the chip, it will cause cracking of the chip due to the thermal expansion and contraction. When capacitors are mounted on a fluorine resin printed circuit board or on a single-layered glass epoxy board, it may also cause cracking of the chip for the same reason.

Pattern Forms



### 2. Land Dimensions

2-1. Chip capacitors can be cracked due to the stress of PCB bending, etc. if the land area is larger than needed and has an excess amount of solder. Please refer to the land dimensions in table 1 for flow soldering, table 2 for reflow soldering.

Please confirm the suitable land dimension by evaluating of the actual SET / PCB.

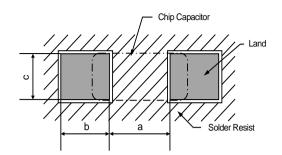


Table 1 Flow Soldering Method

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Series	Chip Dimension (L/W) Code	Chip(L×W)	а	b	С
GRT	18	1.6×0.8	0.6 to 1.0	0.8 to 0.9	0.6 to 0.8
GRT	21	2.0×1.25	1.0 to 1.2	0.9 to 1.0	0.8 to 1.1
GRT	31	3.2×1.6	2.2 to 2.6	1.0 to 1.1	1.0 to 1.4

Flow soldering can only be used for products with a chip size of 1.6x0.8mm to 3.2x1.6mm.

(in mm)

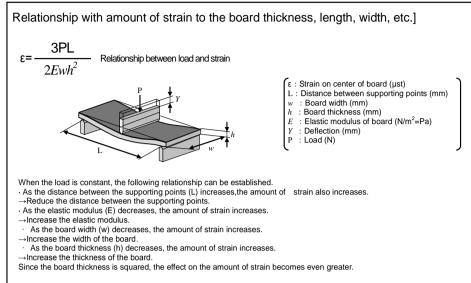
Table 2 Reflow Soldering Method

Series	Chip Dimension (L/W) Code	Chip(L×W)	а	b	С
GRT	03	0.6×0.3	0.2 to 0.3	0.2 to 0.35	0.2 to 0.4
GRT	15	1.0×0.5	0.3 to 0.5	0.35 to 0.45	0.4 to 0.6
GRT	18	1.6×0.8	0.6 to 0.8	0.6 to 0.7	0.6 to 0.8
GRT	21	2.0×1.25	1.0 to 1.2	0.6 to 0.7	0.8 to 1.1
GRT	31	3.2×1.6	2.2 to 2.4	0.8 to 0.9	1.0 to 1.4
GRT	32	3.2×2.5	2.0 to 2.4	1.0 to 1.2	1.8 to 2.3

(in mm)

#### 3. Board Design

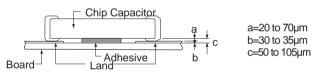
When designing the board, keep in mind that the amount of strain which occurs will increase depending on the size and material of the board.



#### 2.Adhesive Application

1. Thin or insufficient adhesive can cause the chips to loosen or become disconnected during flow soldering.

The amount of adhesive must be more than dimension c, shown in the drawing at right, to obtain the correct bonding strength. The chip's electrode thickness and land thickness must also be taken into consideration.



2. Low viscosity adhesive can cause chips to slip after mounting. The adhesive must have a viscosity of 5000Pa • s (500ps) min. (at 25°C)

## 3. Adhesive Coverage

Size (LxW) (in mm)	Adhesive Coverage*			
1.6 × 0.8	0.05mg min.			
2.0 × 1.25	0.1mg min.			
3.2 × 1.6	0.15mg min.			

\*Nominal Value

## 3.Adhesive Curing

 Insufficient curing of the adhesive can cause chips to disconnect during flow soldering and causes deterioration in the insulation resistance between the terminations due to moisture absorption. Control curing temperature and time in order to prevent insufficient hardening.

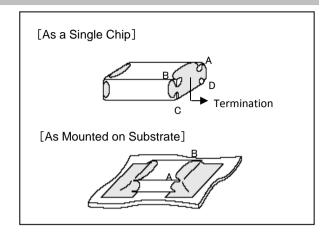
## 4.Flux (for Flow soldering)

- 1. An excessive amount of flux generates a large quantity of flux gas, which can cause a deterioration of solderability, so apply flux thinly and evenly throughout. (A foaming system is generally used for flow solderring.)
- 2. Flux containing too high a percentage of halide may cause corrosion of the terminations unless there is sufficient cleaning. Use flux with a halide content of 0.1% max.
- 3. Do not use strong acidic flux.
- 4. Do not use water-soluble flux.\*

  (\*Water-soluble flux can be defined as non-rosin type flux including wash-type flux and non-wash-type flux.)

## 5.Flow Soldering

Set temperature and time to ensure that leaching of the terminations does not exceed 25% of the chip end area as a single chip (full length of the edge A-B-C-D shown at right) and 25% of the length A-B shown as mounted on substrate.



## 6.Reflow soldering

The halogen system substance and organic acid are included in solder paste, and a chip corrodes by this kind of solder paste.

Do not use strong acid flux.

Do not use water-soluble flux.\*

(\*Water-soluble flux can be defined as non-rosin type flux including wash-type flux and non-wash-type flux.)

#### 7.Washing

- Please evaluate the capacitor using actual cleaning equipment and conditions to confirm the quality, and select the solvent for cleaning.
- 2. Unsuitable cleaning solvent may leave residual flux or other foreign substances, causing deterioration of electrical characteristics and the reliability of the capacitors.
- 3. Select the proper cleaning conditions.
- 3-1. Improper cleaning conditions (excessive or insufficient) may result in the deterioration of the performance of the capacitors.

## 8.Coating

- 1. A crack may be caused in the capacitor due to the stress of the thermal contraction of the resin during curing process. The stress is affected by the amount of resin and curing contraction. Select a resin with low curing contraction. The difference in the thermal expansion coefficient between a coating resin or a molding resin and the capacitor may cause the destruction and deterioration of the capacitor such as a crack or peeling, and lead to the deterioration of insulation resistance or dielectric breakdown.
  - Select a resin for which the thermal expansion coefficient is as close to that of the capacitor as possible. A silicone resin can be used as an under-coating to buffer against the stress.
- Select a resin that is less hygroscopic.
   Using hygroscopic resins under high humidity conditions may cause the deterioration of the insulation resistance of a capacitor. An epoxy resin can be used as a less hygroscopic resin.
- 3. The halogen system substance and organic acid are included in coating material, and a chip corrodes by the kind of Coating material. Do not use strong acid type.

#### Others

#### 1.Transportation

- 1. The performance of a capacitor may be affected by the conditions during transportation.
- 1-1. The capacitors shall be protected against excessive temperature, humidity and mechanical force during transportation.
  - (1) Climatic condition
    - · low air temperature : -40°C
    - · change of temperature air/air : -25°C/+25°C
    - · low air pressure: 30 kPa
    - · change of air pressure : 6 kPa/min.
  - (2) Mechanical condition

Transportation shall be done in such a way that the boxes are not deformed and forces are not directly passed on to the inner packaging.

- 1-2. Do not apply excessive vibration, shock, or pressure to the capacitor.
  - (1) When excessive mechanical shock or pressure is applied to a capacitor, chipping or cracking may occur in the ceramic body of the capacitor.
  - (2) When the sharp edge of an air driver, a soldering iron, tweezers, a chassis, etc. impacts strongly on the surface of the capacitor, the capacitor may crack and short-circuit.
- 1-3. Do not use a capacitor to which excessive shock was applied by dropping etc. A capacitor dropped accidentally during processing may be damaged.

#### 2. Characteristics Evaluation in the Actual System

- 1. Evaluate the capacitor in the actual system,to confirm that there is no problem with the performance and specification values in a finished product before using.
- 2. Since a voltage dependency and temperature dependency exists in the capacitance of high dielectric type ceramic capacitors, the capacitance may change depending on the operating conditions in the actual system. Therefore, be sure to evaluate the various characteristics, such as the leakage current and noise absorptivity, which will affect the capacitance value of the capacitor.
- 3. In addition,voltages exceeding the predetermined surge may be applied to the capacitor by the inductance in the actual system. Evaluate the surge resistance in the actual system as required.



**△** NOTE

- 1.Please make sure that your product has been evaluated in view of your specifications with our product being mounted to your product.
- 2. Your are requested not to use our product deviating from this product specification.
- 3.We consider it not appropriate to include any terms and conditions with regard to the business transaction in the product specifications, drawings or other technical documents. Therefore, if your technical documents as above include such terms and conditions such as warranty clause, product liability clause, or intellectual property infringement liability clause, they will be deemed to be invalid.
- 4.GRT series is manufactured under a quality management system compliant to ISO9001, but is not registered to ISO/TS16949.